采用小型封装的 TPS7A05 1μA 超低 I_Q 200mA 低压降稳压器

1 特性

- 超低 I_Q：1μA（典型值）、3μA（最大值）
  - I_{GND}：在 200mA 下为 6μA（典型值）
- 绝佳的瞬态响应
- 封装：
  - 1.0mm × 1.0mm X2SON (4)
  - 0.65mm × 0.65mm DSBGA (4)
  - SOT-23 (5)
  - SOT-23 (3)
- 输入电压范围：1.4V 至 5.5V
- 输出精度：1% 典型值，3% 最大值
- 可提供固定输出电压：
  - 0.8V 至 3.3V
- 非常低的压降：
  - 200mA 时为 235mV（最大值）(3.3V_{OUT})
- 有源输出放电
- 折返电流限制
- 与 0.47μF 或更大的电容器一起工作时保持稳定

2 应用

- 可穿戴电子产品
- 超极本、平板电脑、电子阅读器
- 始终通电型电源
- 机顶盒
- 游戏控制器、遥控器、玩具、无人机
- 无线手持终端和智能手机
- 便携式和电池供电类设备

3 说明

TPS7A05 是一款超小型低静态电流低压降稳压器 (LDO)，可提供 200mA 的电流以及出色的瞬态性能。该器件的输出范围为 0.8V 至 3.3V，典型精度为 1%。

TPS7A05 具有超低 I_Q (1μA)，消耗的静态电流极低，从而能够在电池供电应用中延长电池 寿命提供了出色的功能性与安全性。该器件可由可再充电的锂离子电池、锂原电池化学物质（如 Li-SOCl2、Li-MnO2）以及两到三节碱性电池供电。

TPS7A05 采用有源下拉电路，用于在器件处于禁用状态时对输出进行快速放电。

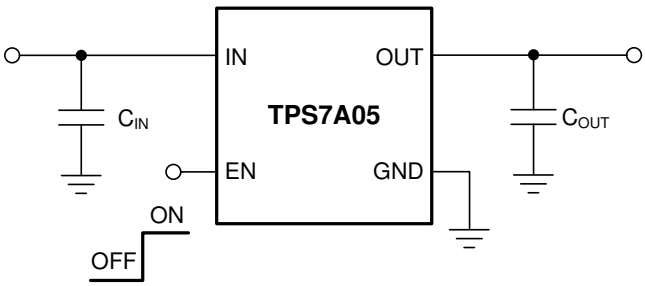
TPS7A05 的完整额定工作温度范围为 T_J = -40°C 至 +125°C，采用标准的 X2SON (DQN)、SOT-23（DBV 和 DBZ）以及 DSBGA (YKA) 封装。

器件信息(1)

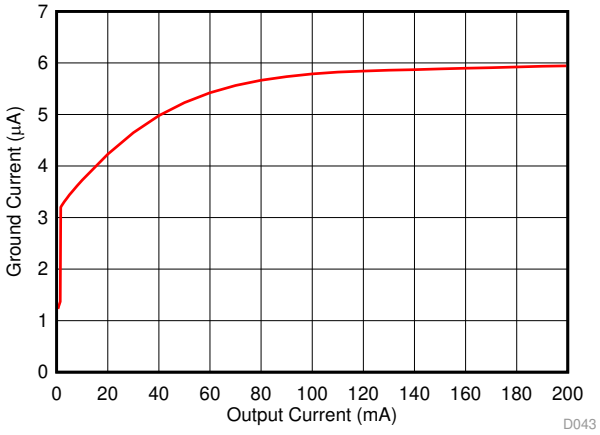
器件型号	封装	封装尺寸（标称值）
TPS7A05	X2SON (4)	1.00mm x 1.00mm
	DSBGA (4)	0.65mm × 0.65mm
	SOT-23 (5)	2.90mm × 1.60mm
	SOT-23 (3)	2.90mm x 1.60mm

(1) 如需了解所有可用封装，请参阅数据表末尾的封装选项附录。

典型应用电路



接地电流与输出电流间的关系



本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。 有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。 TI 不保证翻译的准确性和有效性。 在实际设计之前，请务必参考最新版本的英文版本。

目录

1 特性 ... 1
2 应用 ... 1
3 说明 ... 1
4 修订历史记录 ... 2
5 **Pin Configuration and Functions** ... 4
6 **Specifications** ... 6
6.1 Absolute Maximum Ratings ... 6
6.2 ESD Ratings ... 6
6.3 Recommended Operating Conditions ... 6
6.4 Thermal Information ... 6
6.5 Electrical Characteristics ... 7
6.6 Switching Characteristics ... 9
6.7 Typical Characteristics ... 10
7 **Detailed Description** ... 18
7.1 Overview ... 18
7.2 Functional Block Diagram ... 18
7.3 Feature Description ... 19
7.4 Device Functional Modes ... 21
8 **Application and Implementation** ... 22
8.1 Application Information ... 22
8.2 Typical Application ... 27
9 **Power Supply Recommendations** ... 27
10 **Layout** ... 28
10.1 Layout Guidelines ... 28
10.2 Layout Example ... 28
11 器件和文档支持 ... 29
11.1 器件支持 ... 29
11.2 文档支持 ... 29
11.3 接收文档更新通知 ... 29
11.4 社区资源 ... 29
11.5 商标 ... 29
11.6 静电放电警告 ... 29
11.7 Glossary ... 29
12 机械、封装和可订购信息 ... 30

4 修订历史记录

Changes from Revision C (April 2019) to Revision D — **Page**

- 已更改 将 DBZ 封装从 APL 更改为生产数据 ... 1
- Added DBZ package to *Load Regulation* parameter in *Electrical Characteristics* table ... 7
- Added DBZ package to *Dropout voltage* parameter in *Electrical Characteristics* table ... 8
- 已添加 condition statement to I_Q *vs* V_{IN} *and Temperature* figure ... 10

Changes from Revision B (August 2018) to Revision C — **Page**

- 已添加 向文档添加了 DBZ 封装（作为 APL 发行版） ... 1

Changes from Revision A (May 2018) to Revision B — **Page**

- 已更改 在文档标题中将 *1mm × 1mm* 更改成了小型 ... 1
- 已更改 将 YKA (DSBGA) 封装状态更改成了“生产数据” ... 1
- Added Accuracy for 1.825 V in *Electrical Characteristics* table ... 7
- Changed Output current limit in *Electrical Characteristics* table ... 7
- Added Output current limit for +85°C in *Electrical Characteristics* table ... 7
- Changed Short-circuit current limit in *Electrical Characteristics* table ... 7
- Added Dropout voltage for 1.825 V in *Electrical Characteristics* table ... 8
- 已更改 y-axis scaling and added conditions for I_{OUT} *Transient 0 mA to 100 mA* figure ... 10
- 已更改 y-axis scaling and added conditions for I_{OUT} *Transient 0 mA to 200 mA* figure ... 11
- 已添加 I_{OUT} *Transient 0 mA to 50 mA* figure to I_{OUT} *Transient 3 µA to 3 mA* figure ... 11
- 已添加 slew rate condition to V_{IN} *Transient* figures (I_{OUT} = 100 mA and I_{OUT} = 200 mA) ... 12
- 已添加 V_{IN} *Transient* figures (I_{OUT} = 150 mA and I_{OUT} = 20 mA) ... 13
- 已添加 V_{IN} condition to *PSRR vs Frequency and* I_{OUT} figure (V_{OUT} = 1.8 V) ... 16

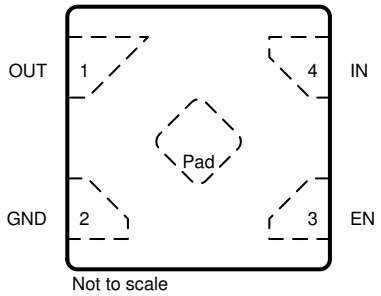
版权 © 2018–2019, Texas Instruments Incorporated

Changes from Original (February 2018) to Revision A **Page**

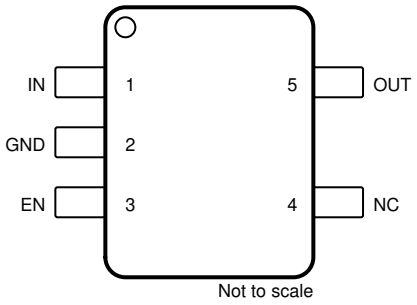
- 已发布至生产 1

5 Pin Configuration and Functions

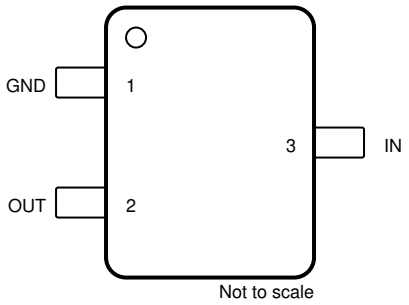
DQN Package
1-mm × 1-mm, 4-Pin X2SON
Top View



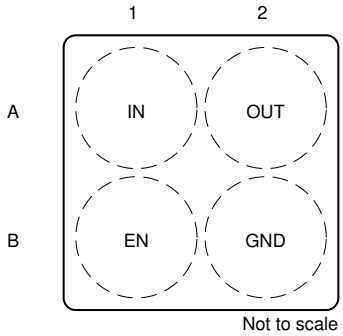
DBV Package
5-Pin SOT-23
Top View



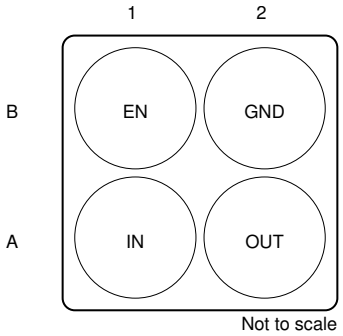
DBZ Package
3-Pin SOT-23
Top View



YKA Package
4-Pin DSBGA, 0.35-mm Pitch
Top View



YKA Package
4-Pin DSBGA, 0.35-mm Pitch
Bottom View



Copyright © 2018–2019, Texas Instruments Incorporated

Pin Functions

PIN					I/O	DESCRIPTION
NAME	DQN	DBV	DBZ	YKA		
IN	4	1	3	A1	Input	Input pin. For best transient response and to minimize input impedance, use the recommended value or larger ceramic capacitor from IN to ground as listed in the *Recommended Operating Conditions* table. Place the input capacitor as close to input of the device as possible.
EN	3	3	—	B1	Input	Enable pin. Driving this pin to logic high enables the device; driving this pin to logic low disables the device. If enable functionality is not required, this pin must be connected to IN. V_{EN} must not exceed V_{IN}.
GND	2	2	1	B2	—	Ground pin. This pin must be connected to ground on the board.
OUT	1	5	2	A2	Output	Regulated output pin. A capacitor is required from OUT to ground for stability. For best transient response, use the nominal recommended value or larger ceramic capacitor from OUT to ground. Follow the recommended capacitor value as listed in the *Recommended Operating Conditions* table. Place the output capacitor as close to output of the device as possible.
NC	—	4	—	—	—	No connect pin. This pin is not internally connected. Connect to ground or leave floating.
Thermal pad	Pad	—	—	—	—	Connect the thermal pad to a large-area ground plane. This pad is not an electrical connection to the device ground.

Copyright © 2018–2019, Texas Instruments Incorporated

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Voltage[2]	IN	–0.3	6.0	V
	EN	–0.3	V_{IN} + 0.3	
	OUT	–0.3	V_{IN} + 0.3 or 3.6[3]	
Current	Maximum output current	Internally limited		A
Temperature	Operating junction temperature, T_J	–40	125	°C
	Storage temperature, T_{stg}	–65	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages with respect to GND.
(3) V_{IN} + 0.3 V or 3.6 V (whichever is smaller)

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{IN}	Input supply voltage	1.4		5.5	V
V_{EN}	Enable supply voltage	0		V_{IN}	V
V_{OUT}	Nominal output voltage range	0.8		3.3	V
I_{OUT}	Output current[1]	0		200	mA
C_{IN}	Input capacitor		1		µF
C_{OUT}	Output capacitor	0.47	1	22	µF
T_J	Operating junction temperature	–40		125	°C

(1) Output current of 10 µA minimum required to meet output voltage accuracy specification.

6.4 Thermal Information

THERMAL METRIC[1]		TPS7A05				UNIT
		DBZ (SOT-23)	DBV (SOT-23)	DQN (X2SON)	YKA (DSBGA)	
		3 PINS	5 PINS	4 PINS	4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	267.3	185.6	144.1	198.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	103.5	104.3	137.9	2.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	98.0	54.5	83.5	66.9	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	9.2	31.0	5.3	0.9	°C/W
Y_{JB}	Junction-to-board characterization parameter	97.4	54.5	83.8	76.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	71.8	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

Copyright © 2018–2019, Texas Instruments Incorporated

6.5 Electrical Characteristics

specified at T_J = –40°C to +125°C, V_{IN} = $V_{OUT(nom)}$ + 0.5 V or 1.4 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted); typical values are at T_J = 25°C.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
	Nominal accuracy(1)	V_{OUT} ≥ 1.0 V, T_J = 25°C		–1%		1%	
		V_{OUT} < 1.0 V, T_J = 25°C		–10		10	mV
	Accuracy over temperature(1)	V_{OUT} ≥ 1.0 V, T_J = –40°C to +85°C		–2%		2%	
		V_{OUT} ≥ 1.0 V		–3%		3%	
		V_{OUT} < 1.0 V, T_J = –40°C to +85°C		–20		20	mV
		V_{OUT} < 1.0 V		–30		30	
		V_{OUT} = 1.825 V, T_J = +10℃ to +45℃, I_{OUT} = 100 µA		–0.9%		0.9%	
$\Delta V_{OUT(\Delta VIN)}$	Line regulation	$V_{OUT(nom)}$ + 0.5 V ≤ V_{IN} ≤ 5.5 V(2), T_J = –40°C to +85°C			5	16.5	mV
		$V_{OUT(nom)}$ + 0.5 V ≤ V_{IN} ≤ 5.5 V(2)				18	
$\Delta V_{OUT(\Delta IOUT)}$	Load regulation(3)	100 µA ≤ I_{OUT} ≤ 200 mA, V_{IN} = $V_{OUT(nom)}$ + $V_{DO(max)}$ + 0.1 V, T_J = –40°C to +85°C	DBV, DQN, YKA		20	43	mV
			DBZ		27	50	
		100 µA ≤ I_{OUT} ≤ 200 mA, V_{IN} = $V_{OUT(nom)}$ + $V_{DO(max)}$ + 0.1 V	DBV, DQN, YKA			55	
			DBZ			62	
I_{GND}	Ground current	T_J = 25°C, I_{OUT} = 1 µA		0.6	1	1.3	µA
		I_{OUT} = 1 µA, T_J = –40°C to +85°C				2	
		I_{OUT} = 1 µA				3	
I_{SHDN}	Shutdown current	V_{EN} = 0.4 V, 1.4 V ≤ V_{IN} ≤ 5.5 V, T_J = 25°C			100	300	nA
I_{CL}	Output current limit	V_{OUT} = 90% × $V_{OUT(nom)}$, V_{IN} = $V_{OUT(nom)}$ + $V_{DO(max)}$ + 0.5 V		210	450	700	mA
I_{CL}	Output current limit	V_{OUT} = 90% × $V_{OUT(nom)}$, V_{IN} = $V_{OUT(nom)}$ + $V_{DO(max)}$ + 0.5 V, T_J = 0°C to +85°C		250	450	700	mA
I_{SC}	Short-circuit current limit	V_{OUT} = 0 V			65	150	mA

(1) I_{OUT} ≥ 10 µA required to meet accuracy specifications.
(2) V_{IN} = 1.4 V for V_{OUT} ≤ 0.9 V.
(3) Load Regulation is normalized to the output voltage at I_{OUT} = 1 mA.

Copyright © 2018–2019, Texas Instruments Incorporated

Electrical Characteristics (continued)

specified at T_J = –40°C to +125°C, V_{IN} = $V_{OUT(nom)}$ + 0.5 V or 1.4 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted); typical values are at T_J = 25°C.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{DO}	Dropout voltage (4)	I_{OUT} = 200 mA, T_J = –40°C to +85°C	0.8 V ≤ V_{OUT} < 1.0 V			915	mV
			1.0 V ≤ V_{OUT} < 1.2 V			758	
			1.2 V ≤ V_{OUT} < 1.5 V			609	
			1.5 V ≤ V_{OUT} < 1.8 V			469	
			1.8 V ≤ V_{OUT} < 2.5 V			341	
			2.5 V ≤ V_{OUT} < 3.3 V			275	
			V_{OUT} = 3.3 V			212	
		I_{OUT} = 200 mA	0.8 V ≤ V_{OUT} < 1.0 V			1004	
			1.0 V ≤ V_{OUT} < 1.2 V			837	
			1.2 V ≤ V_{OUT} < 1.5 V			679	
			1.5 V ≤ V_{OUT} < 1.8 V			525	
			1.8 V ≤ V_{OUT} < 2.5 V			382	
			2.5 V ≤ V_{OUT} < 3.3 V			308	
			V_{OUT} = 3.3 V			235	
		I_{OUT} = 200 mA, T_J = –40°C to +85°C, DBZ Package	1.8 V ≤ V_{OUT} < 2.5 V			351	
			2.5 V ≤ V_{OUT} < 3.3 V			285	
			V_{OUT} = 3.3 V			222	
		I_{OUT} = 200 mA, DBZ Package	1.8 V ≤ V_{OUT} < 2.5 V			392	
			2.5 V ≤ V_{OUT} < 3.3 V			318	
			V_{OUT} = 3.3 V			245	
		I_{OUT} = 100 µA, T_J = +10℃ to +45℃	V_{OUT} = 1.825 V			20	
PSRR	Power-supply rejection ratio	f = 1 kHz, I_{OUT} = 30 mA			40		dB
		f = 500 kHz, I_{OUT} = 30 mA			30		
		f = 1 MHz, I_{OUT} = 30 mA			40		
V_N	Output voltage noise	BW = 10 Hz to 100 kHz, V_{OUT} = 1.2 V, I_{OUT} = 30 mA			180		$µV_{RMS}$
V_{UVLO}	UVLO threshold	V_{IN} rising		1.21	1.3	1.37	V
$V_{UVLO(HYST)}$	UVLO hysteresis	V_{IN} falling			40		mV
V_{UVLO}	UVLO threshold	V_{IN} falling		1.17		1.33	V
$V_{EN(HI)}$	EN pin logic high voltage			0.9			V
$V_{EN(LO)}$	EN pin logic low voltage					0.4	V
I_{EN}	EN pin current	V_{EN} = V_{IN} = 5.5 V			10		nA
$R_{PULLDOWN}$	Pulldown resistor	V_{IN} = 3.3 V, P version only			120		Ω
T_{sd}	Thermal shutdown temperature	Shutdown, temperature increasing			160		°C
		Reset, temperature decreasing			140		

(4) Dropout is measured by ramping V_{IN} down until V_{OUT} = $V_{OUT(nom)}$ – 5%.

Copyright © 2018–2019, Texas Instruments Incorporated

6.6 Switching Characteristics

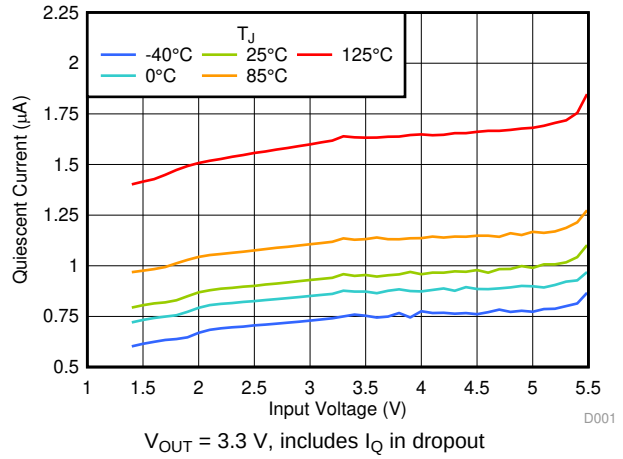
specified at T_J = –40 to +125°C, V_{IN} = $V_{OUT(nom)}$ + $V_{DO(max)}$ + 0.5 V, I_{OUT} = 10 mA, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted); typical values are at T_J = 25°C.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{STR}	Start-up time(1)	From EN assertion to V_{OUT} = 95% × $V_{OUT(nom)}$, V_{OUT} = 1.8 V		1.5	2.8	ms

(1) See the *Special Considerations When Ramping Down IN and Enable* section for details on minimum ramp down rates to ensure specified start-up time.

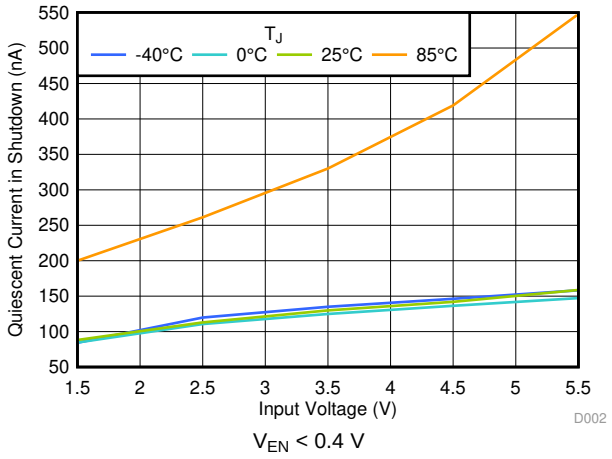
6.7 Typical Characteristics

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



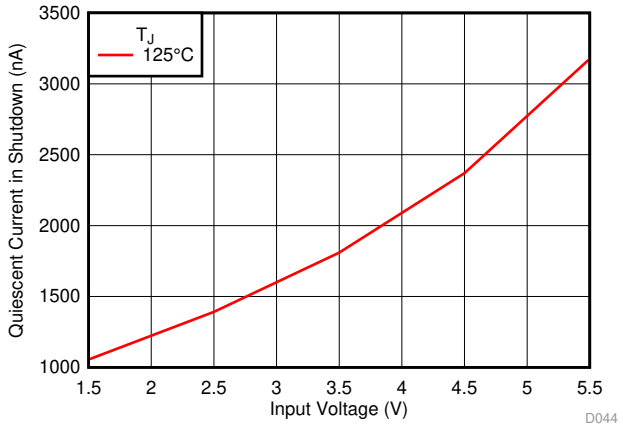
V_{OUT} = 3.3 V, includes I_Q in dropout

图 1. I_Q vs V_{IN} and Temperature



V_{EN} < 0.4 V

图 2. I_{SHDN} vs V_{IN} and Temperature



V_{EN} < 0.4 V

图 3. I_{SHDN} vs V_{IN} and Temperature

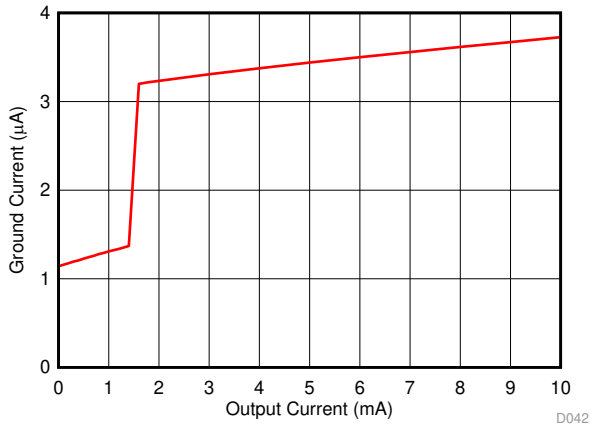


图 4. I_{GND} vs I_{OUT} up to 10 mA

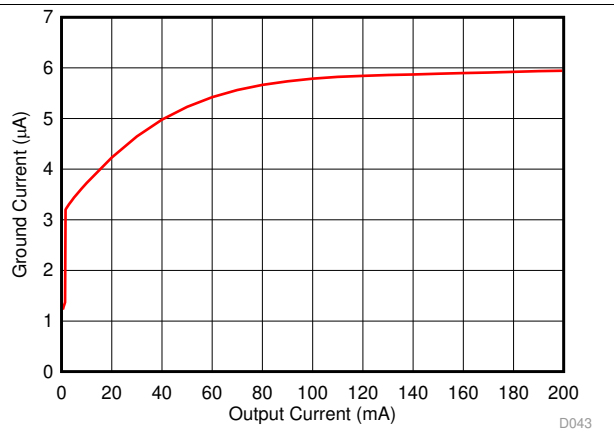
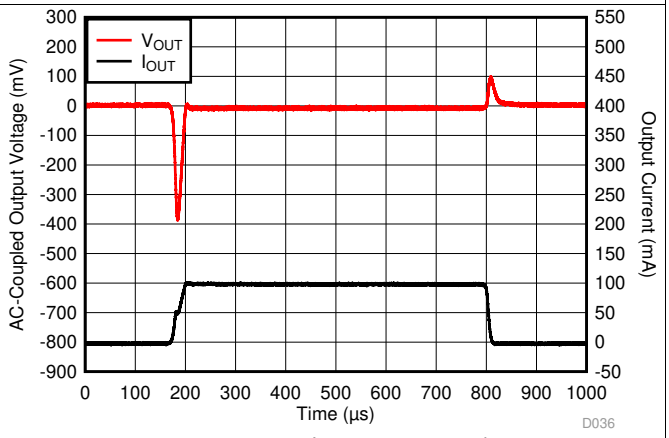


图 5. I_{GND} vs I_{OUT} up to 200 mA



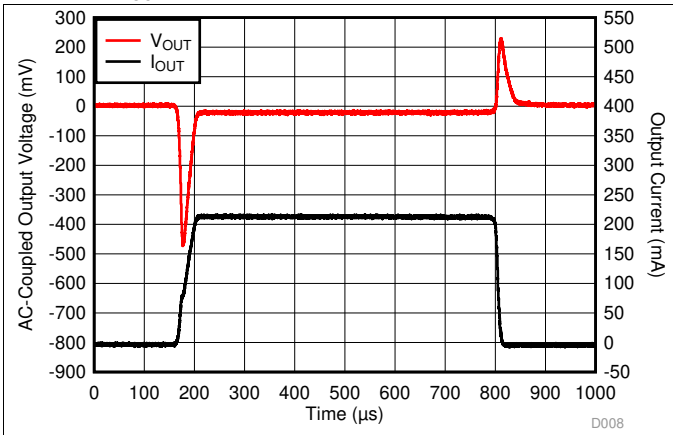
Output current slew rate = 3.3 mA/µs

图 6. I_{OUT} Transient 0 mA to 100 mA

版权 © 2018–2019, Texas Instruments Incorporated

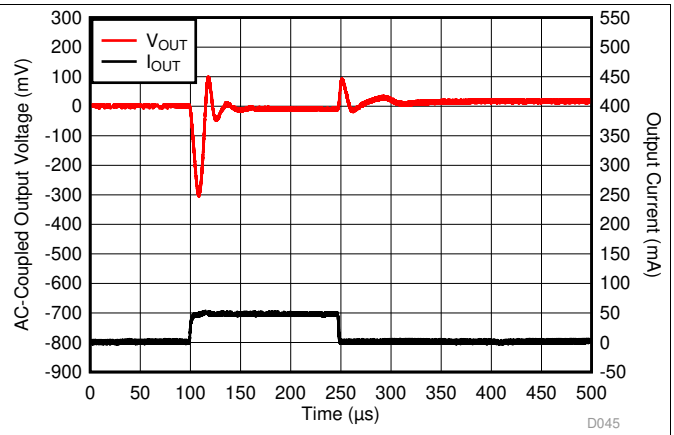
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



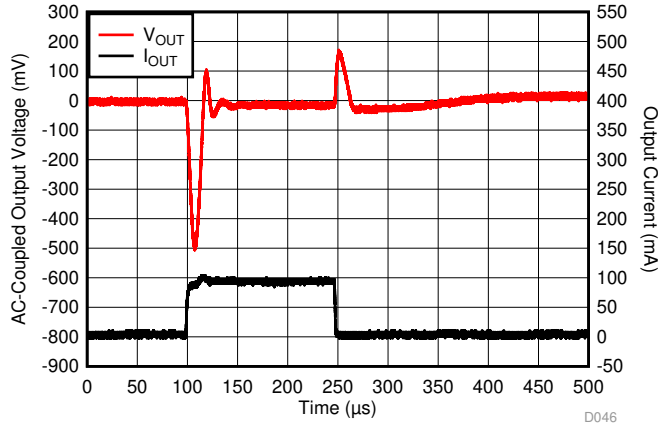
Output current slew rate = 6.6 mA/µs

图 7. I_{OUT} Transient 0 mA to 200 mA



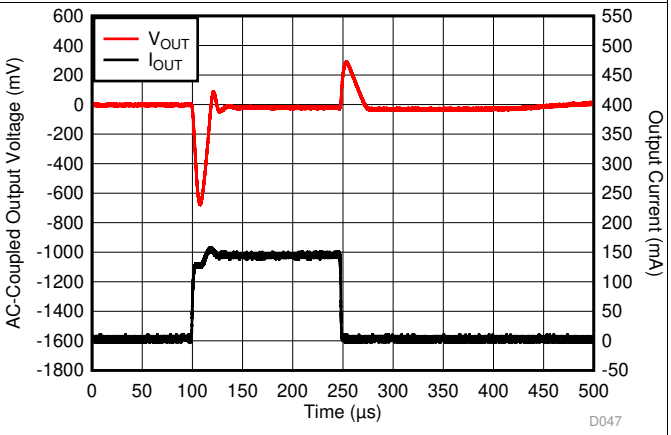
Output current slew rate = 50 mA/µs

图 8. I_{OUT} Transient 0 mA to 50 mA



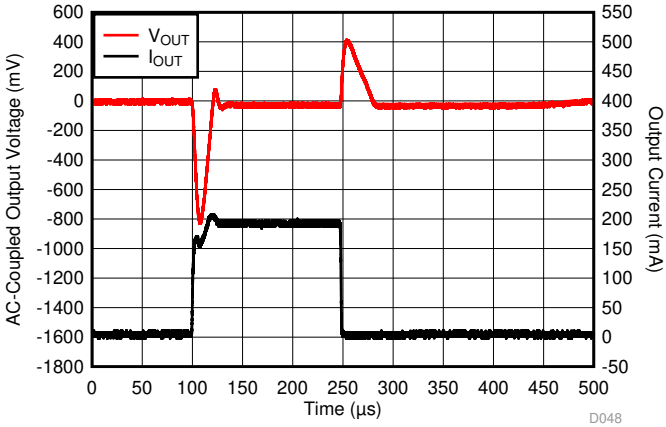
Output current slew rate = 100 mA/µs

图 9. I_{OUT} Transient 0 mA to 100 mA



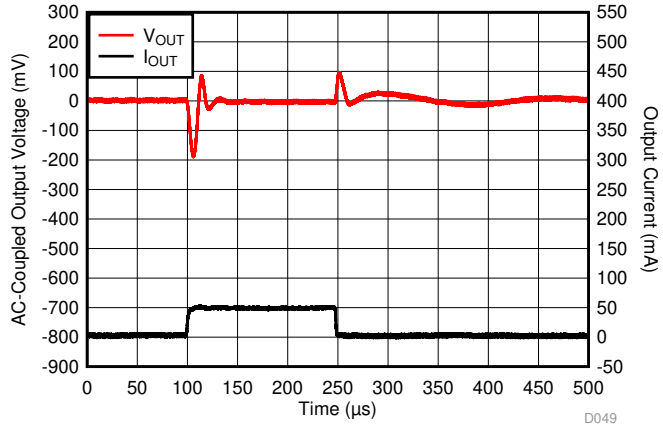
Output current slew rate = 150 mA/µs

图 10. I_{OUT} Transient 0 mA to 150 mA



Output current slew rate = 200 mA/µs

图 11. I_{OUT} Transient 0 mA to 200 mA

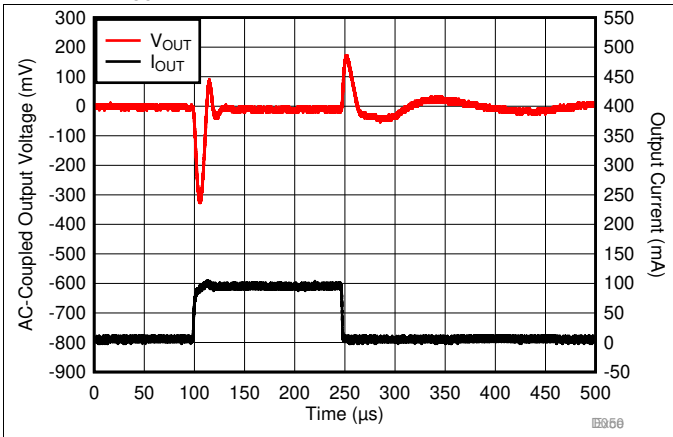


Output current slew rate = 50 mA/µs

图 12. I_{OUT} Transient 1 mA to 50 mA

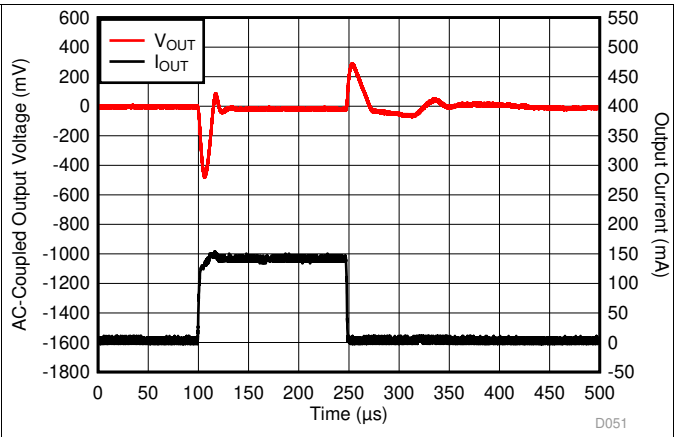
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



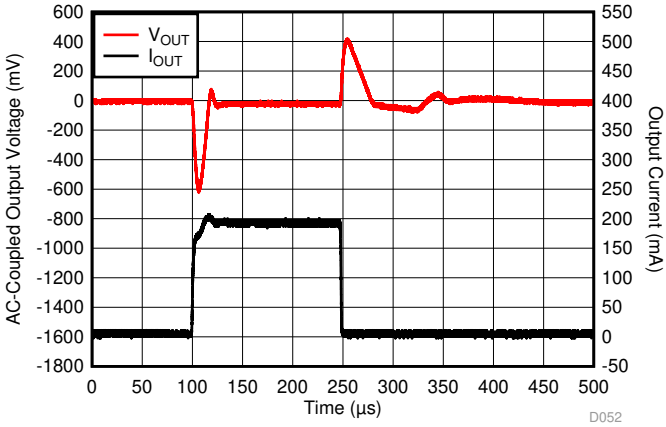
Output current slew rate = 100 mA/µs

图 13. I_{OUT} Transient 1 mA to 100 mA



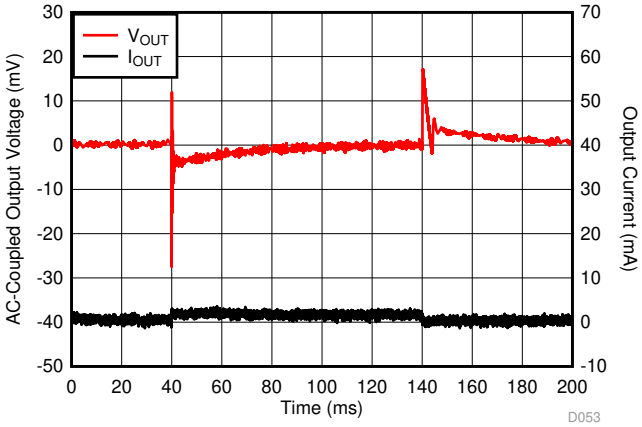
Output current slew rate = 150 mA/µs

图 14. I_{OUT} Transient 1 mA to 150 mA



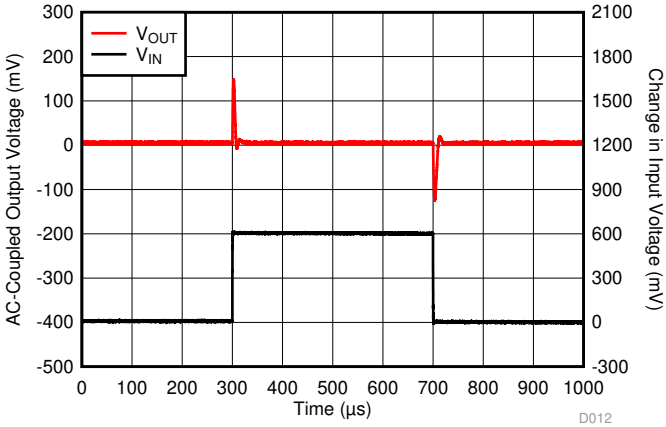
Output current slew rate = 200 mA/µs

图 15. I_{OUT} Transient 1 mA to 200 mA



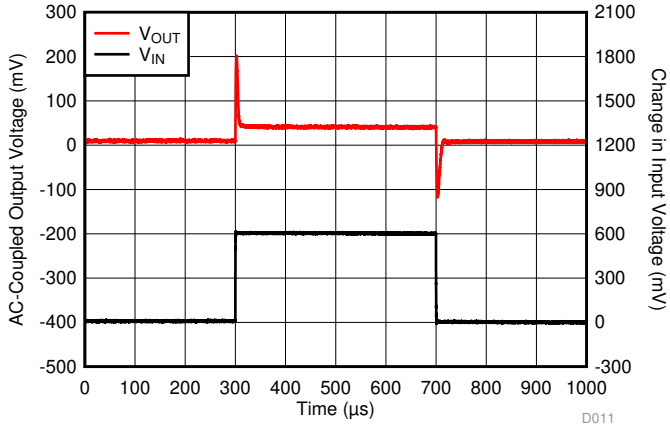
C_{IN} = C_{OUT} = 10 µF, output current slew rate = 3 mA/µs

图 16. I_{OUT} Transient 3 µA to 3 mA



I_{OUT} = 100 mA, input voltage slew rate = 0.6 V/µs

图 17. V_{IN} Transient



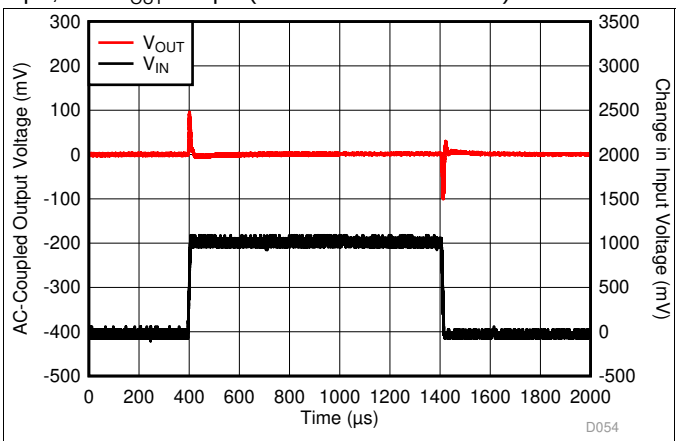
I_{OUT} = 200 mA, input voltage slew rate = 0.6 V/µs

图 18. V_{IN} Transient

版权 © 2018–2019, Texas Instruments Incorporated

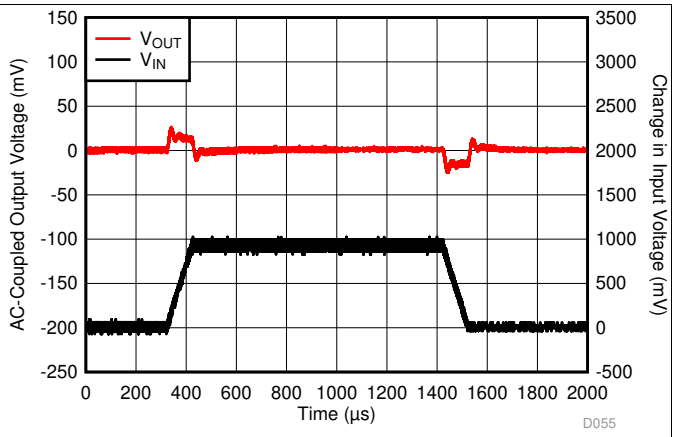
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



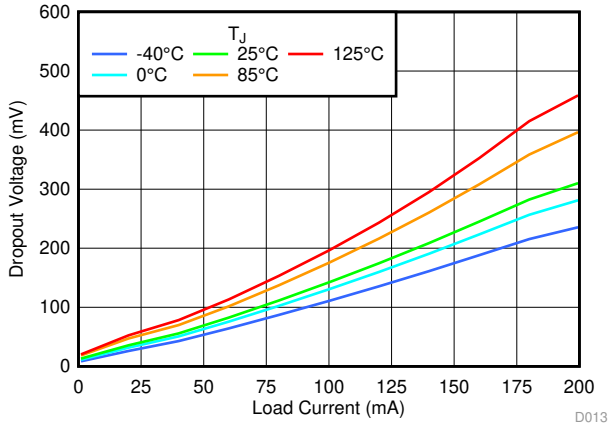
I_{OUT} = 150 mA, input voltage slew rate = 0.1 V/µs

图 19. V_{IN} Transient



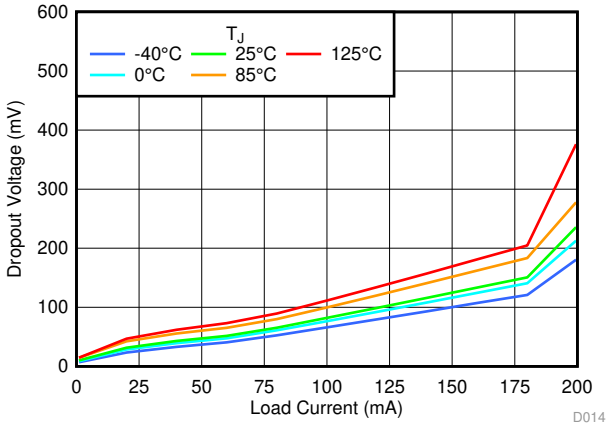
I_{OUT} = 20 mA, input voltage slew rate = 0.01 V/µs

图 20. V_{IN} Transient



V_{OUT} = 1.8 V

图 21. Dropout vs I_{OUT} and Temperature



V_{OUT} = 3.3 V

图 22. Dropout vs I_{OUT} and Temperature

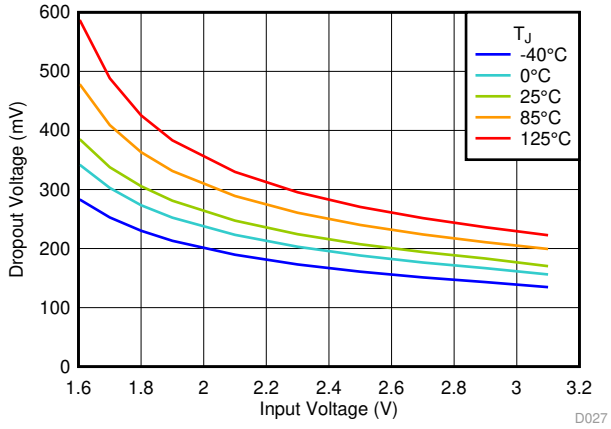
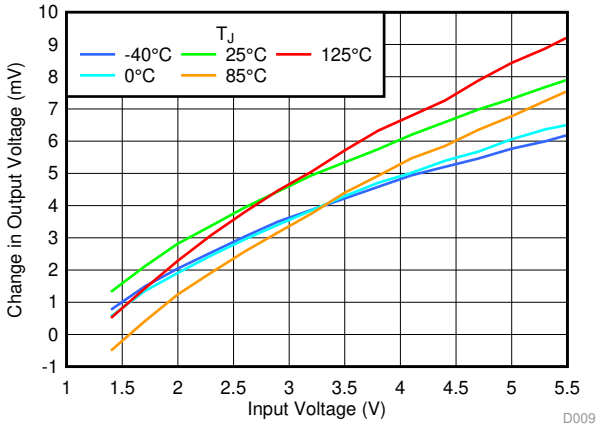


图 23. Dropout vs V_{IN} and Temperature

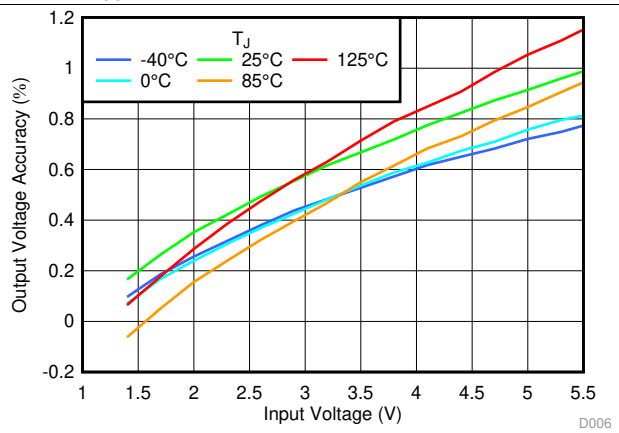


V_{OUT} = 0.8 V

图 24. Line Regulation V_{IN} and Temperature

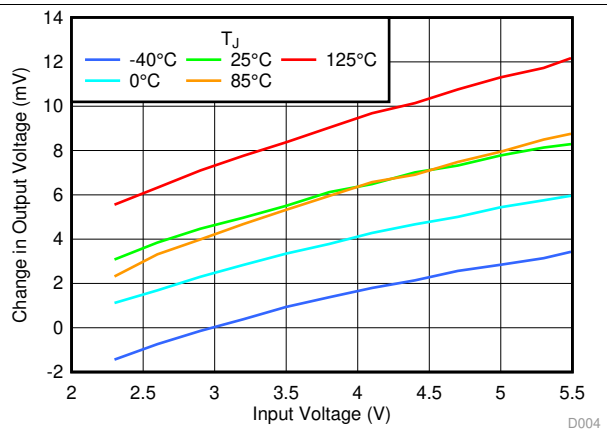
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



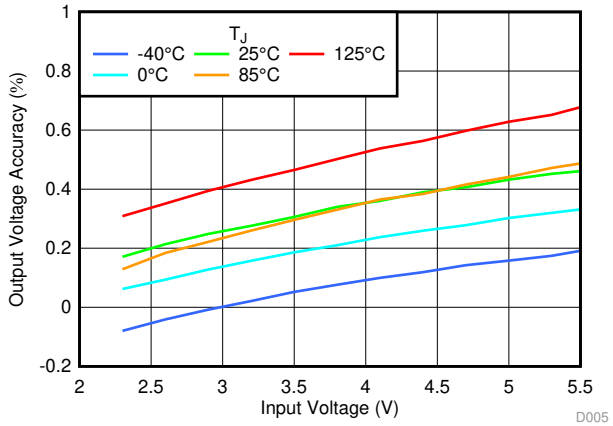
V_{OUT} = 0.8 V

图 25. Output Accuracy V_{IN} and Temperature



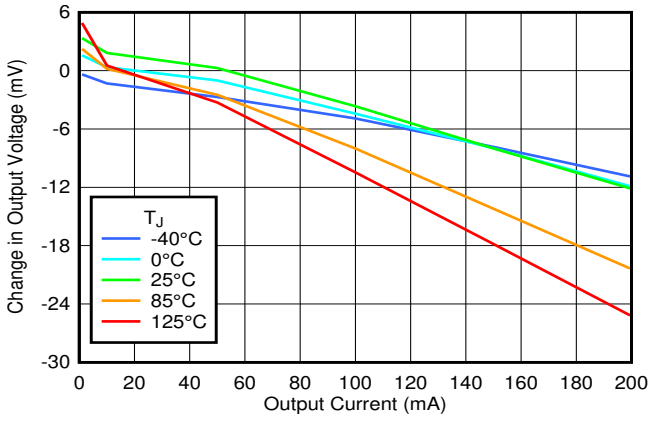
V_{OUT} = 1.8 V

图 26. Line Regulation V_{IN} and Temperature



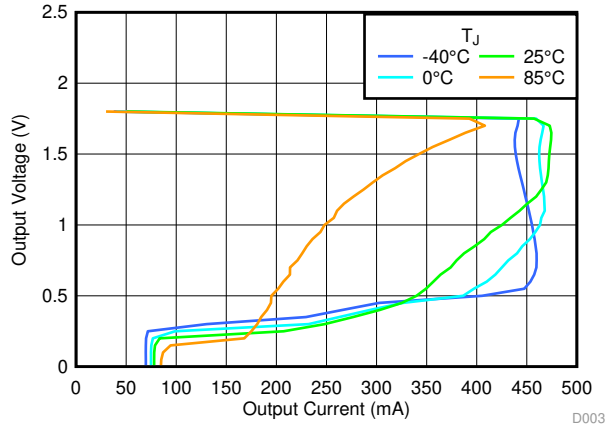
V_{OUT} = 1.8 V

图 27. Output Accuracy V_{IN} and Temperature



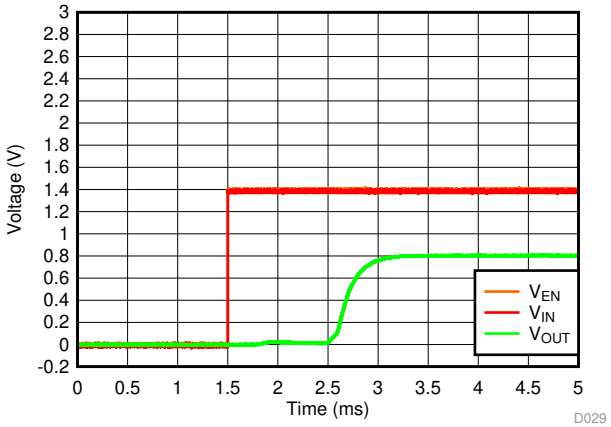
V_{OUT} = 1.8 V

图 28. Load Regulation vs I_{OUT} and Temperature



V_{OUT} = 1.8 V

图 29. Foldback Current Limit vs I_{OUT} and Temperature



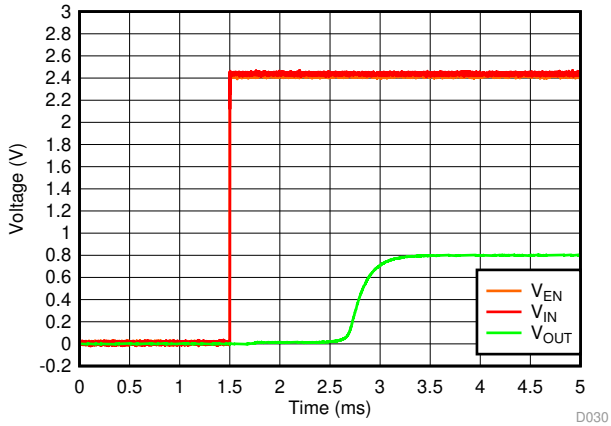
V_{OUT} = 0.8 V, I_{OUT} = 1 mA

图 30. Startup With V_{EN} = V_{IN}

版权 © 2018–2019, Texas Instruments Incorporated

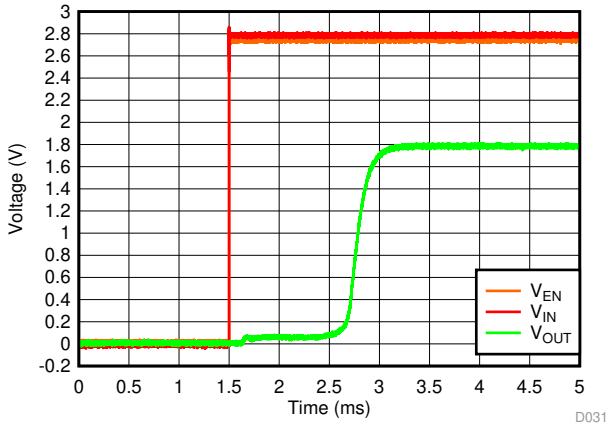
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



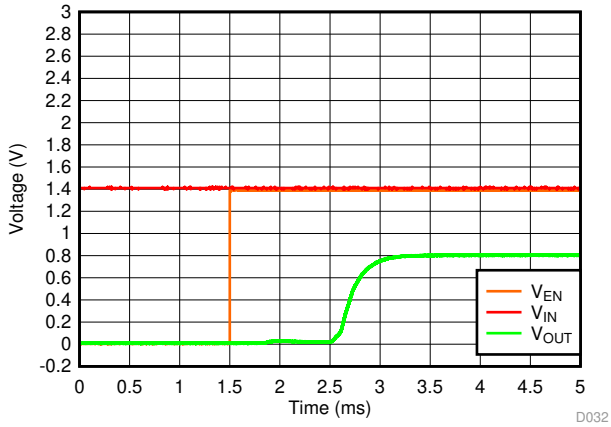
V_{OUT} = 0.8 V, I_{OUT} = 30 mA

图 31. Startup With V_{EN} = V_{IN}



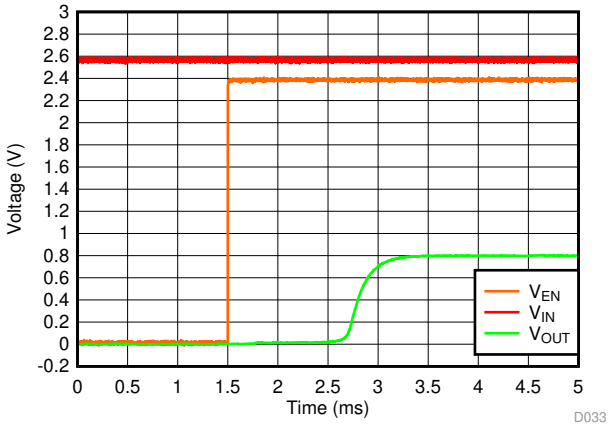
V_{OUT} = 1.8 V, I_{OUT} = 30 mA

图 32. Startup With V_{EN} = V_{IN}



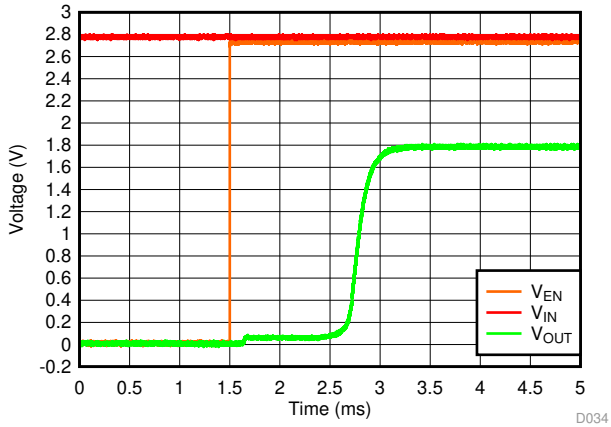
V_{OUT} = 0.8 V, I_{OUT} = 1 mA

图 33. Startup With Separate V_{IN} and V_{EN}



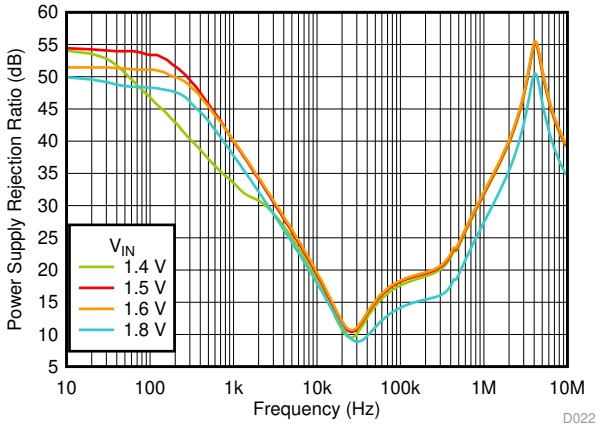
V_{OUT} = 0.8 V, I_{OUT} = 30 mA

图 34. Startup With Separate V_{IN} and V_{EN}



V_{OUT} = 1.8 V, I_{OUT} = 30 mA

图 35. Startup With Separate V_{IN} and V_{EN}

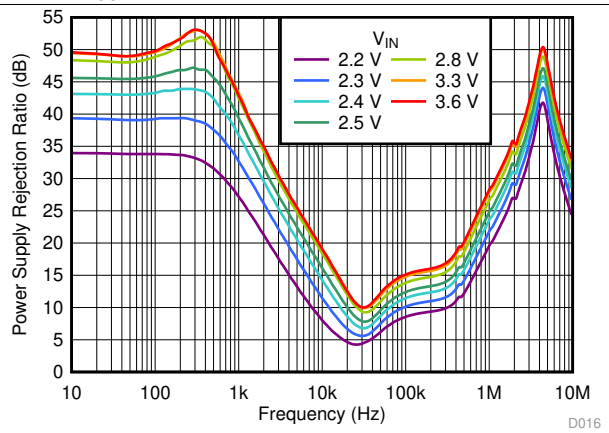


V_{OUT} = 0.8 V, I_{OUT} = 200 mA, C_{OUT} = 1 µF, C_{IN} = 0 µF

图 36. PSRR vs Frequency and V_{IN}

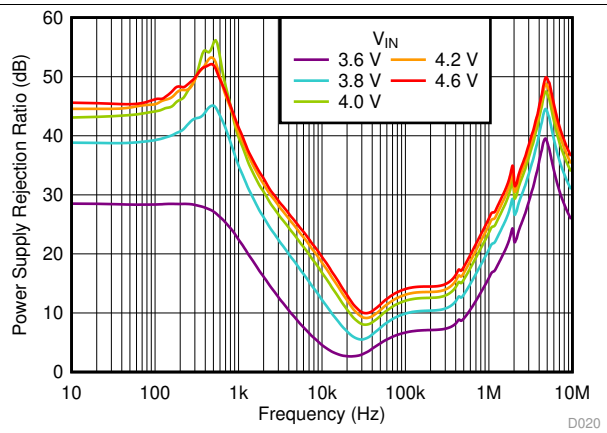
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



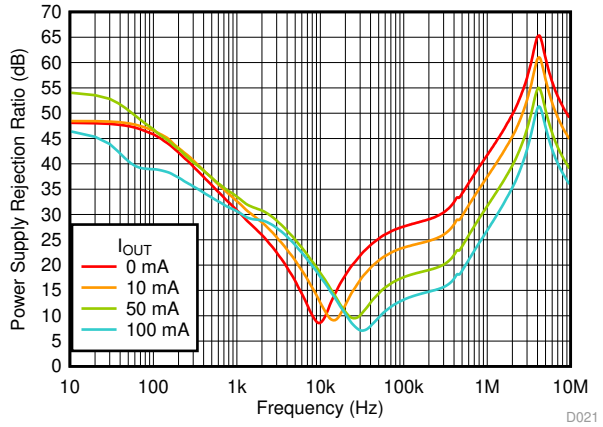
V_{OUT} = 1.8 V, I_{OUT} = 200 mA, C_{OUT} = 1 µF, C_{IN} = 0 µF

图 37. PSRR vs Frequency and V_{IN}



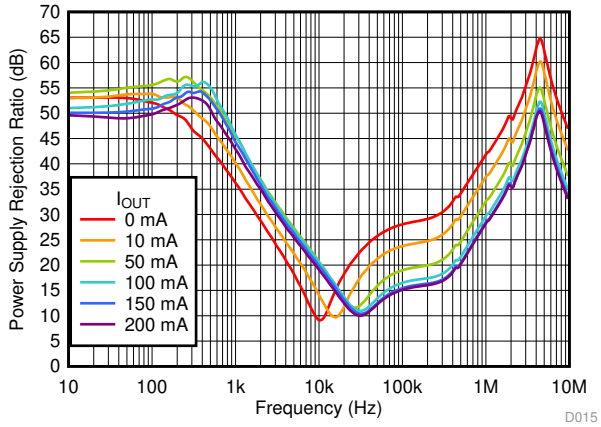
V_{OUT} = 3.3 V, I_{OUT} = 200 mA, C_{OUT} = 1 µF, C_{IN} = 0 µF

图 38. PSRR vs Frequency and V_{IN}



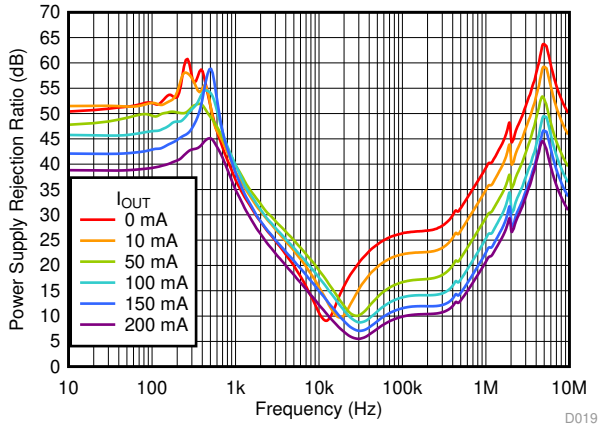
V_{OUT} = 0.8 V, V_{IN} = 1.4 V, C_{OUT} = 1 µF, C_{IN} = 0 µF

图 39. PSRR vs Frequency and I_{OUT}



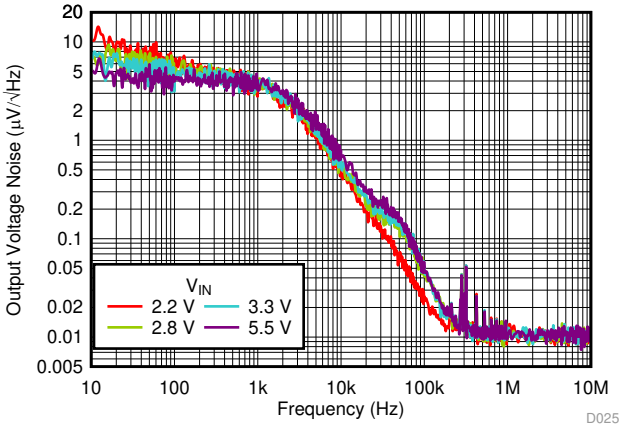
V_{OUT} = 1.8 V, V_{IN} = 2.8 V, C_{OUT} = 1 µF, C_{IN} = 0 µF

图 40. PSRR vs Frequency and I_{OUT}



V_{OUT} = 3.3 V, V_{IN} = 3.8 V, C_{OUT} = 1 µF, C_{IN} = 0 µF

图 41. PSRR vs Frequency and I_{OUT}



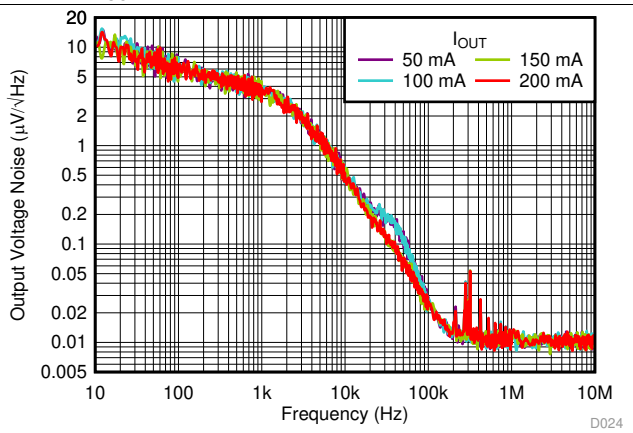
V_{OUT} = 1.8 V, I_{OUT} = 200 mA, C_{OUT} = 1 µF

图 42. Output Noise vs Frequency and V_{IN}

版权 © 2018–2019, Texas Instruments Incorporated

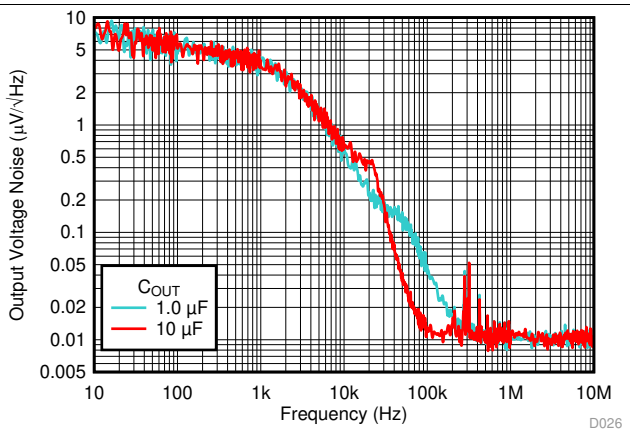
Typical Characteristics (接下页)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2.0 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, and C_{OUT} = 1 µF (unless otherwise noted)



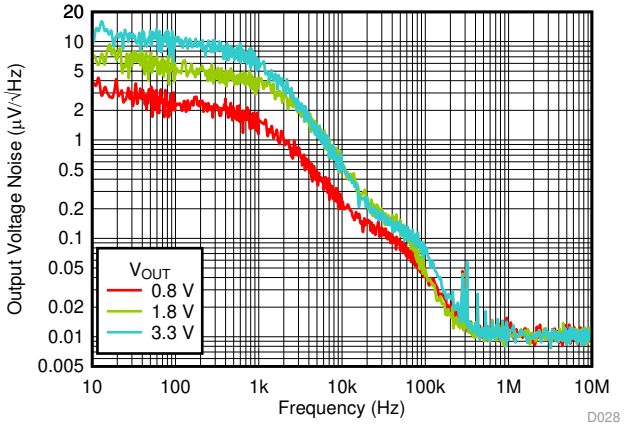
V_{OUT} = 1.8 V, V_{IN} = 2.8 V, C_{OUT} = 1 µF

图 43. Output Noise vs Frequency and I_{OUT}



V_{OUT} = 1.8 V, V_{IN} = 2.8 V, I_{OUT} = 200 mA

图 44. Output Noise vs Frequency and C_{OUT}



V_{IN} = V_{OUT} + 1 V, I_{OUT} = 200 mA, C_{OUT} = 1 µF

图 45. Output Noise vs Frequency and V_{OUT}

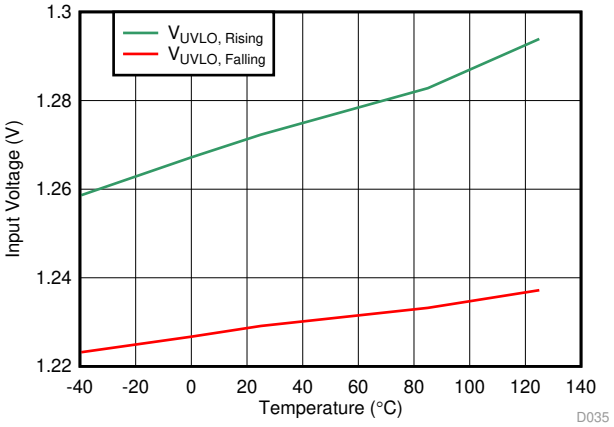


图 46. UVLO V_{IN} Rising and Falling Thresholds vs Temperature

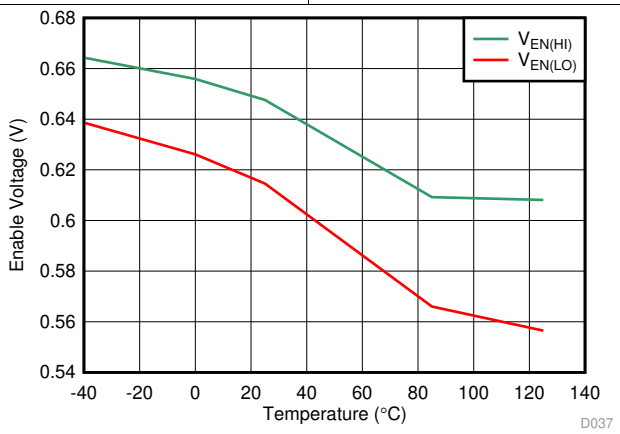


图 47. Enable High and Low Thresholds vs Temperature

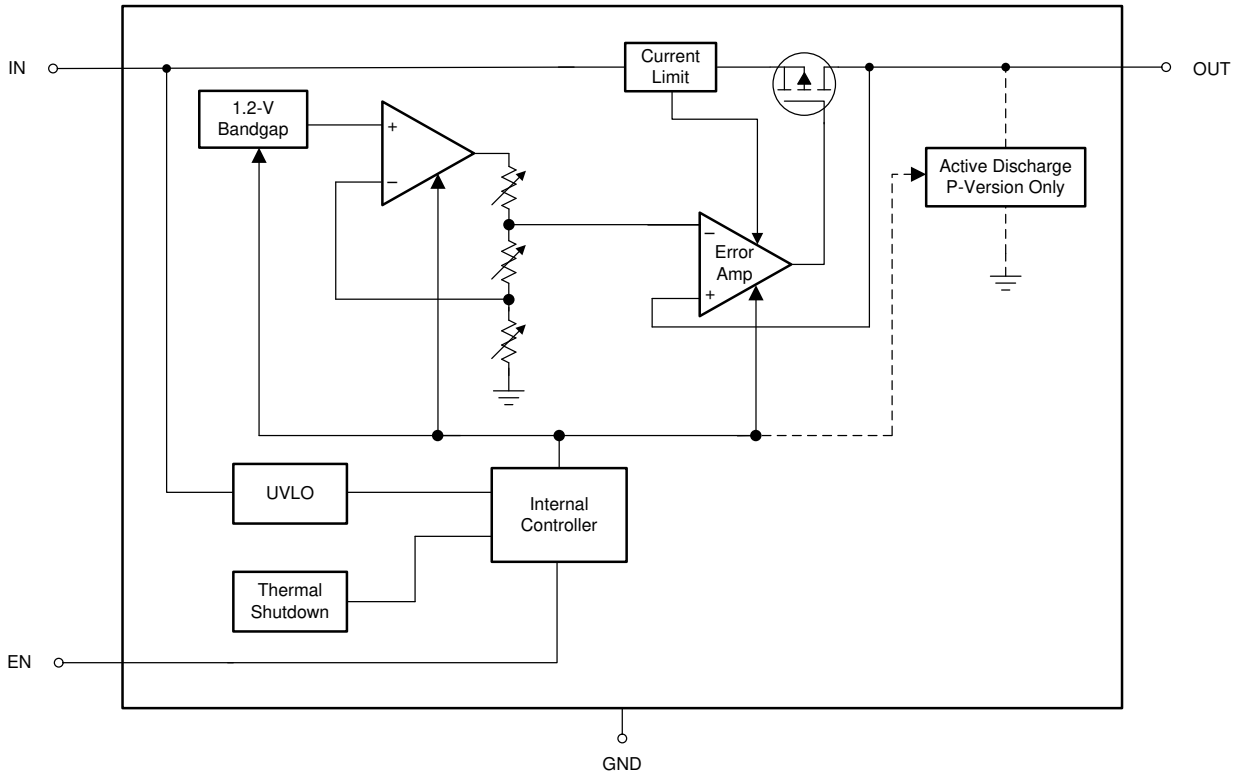
7 Detailed Description

7.1 Overview

The TPS7A05 is a ultra-low I_Q linear voltage regulator that is optimized for excellent transient performance. These characteristics make the TPS7A05 ideal for most battery-powered applications.

This low-dropout regulator (LDO) offers foldback current limit, shutdown, thermal protection, and optional active discharge.

7.2 Functional Block Diagram



版权 © 2018–2019, Texas Instruments Incorporated

7.3 Feature Description

7.3.1 Excellent Transient Response

The device includes several innovative circuits to ensure excellent transient response. Dynamic biasing increases the I_Q for a short duration during transients to extend the closed-loop bandwidth and improve the device response time during transients.

Adaptive biasing increases the I_Q as the dc load current increases, extending the bandwidth of the control loop. The device response time across the output voltage range is constant because of the use of a buffered reference topology, which keeps the control loop in unity gain at any output voltage.

These features give the device a wide loop bandwidth during transients that ensure excellent transient response while maintaining the device low I_Q in steady-state conditions; see the *Application and Implementation* section for more details.

7.3.2 Active Discharge

Devices with this option have an internal pulldown MOSFET that connects a 120-Ω resistor to ground when the device is disabled to actively discharge the output voltage. The active discharge circuit is activated when the device is disabled, in undervoltage lockout (UVLO), or in thermal shutdown.

The discharge time after disabling depends on the output capacitance (C_{OUT}) and the load resistance (R_L) in parallel with the 120-Ω pulldown resistor. 公式 1 calculates the time constant:

$$\tau = \frac{120 \cdot R_L}{120 + R_L} \cdot C_{OUT} \tag{1}$$

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply has collapsed because reverse current can flow from the output to the input. This reverse current flow can cause damage to the device. Limit reverse current to no more than 5% of the device-rated current.

7.3.3 Low I_Q in Dropout

In most LDOs the I_Q significantly increases when the device is placed into dropout, which is especially true for low I_Q LDOs with adaptive biasing. The TPS7A05 detects when operating in dropout and disables the adaptive biasing, minimizing the I_Q increase.

7.3.4 Undervoltage Lockout (UVLO)

The undervoltage lockout (UVLO) circuit monitors the input voltage (V_{IN}) to prevent the device from turning on before V_{IN} rises above the lockout voltage. The UVLO circuit also disables the output of the device when V_{IN} falls below the lockout voltage. If the device includes the optional active discharge, the output is connected to ground with a 120-Ω pulldown resistor when V_{IN} is below the lockout voltage; see the *Application and Implementation* section for more details.

7.3.5 Enable

The enable pin for the device is active high. The output of the device is turned on when the enable pin voltage is greater than the EN pin logic high voltage, and the output of the device is turned off when the enable pin voltage is less than the EN pin logic low voltage. A voltage less than the EN pin logic low voltage on the enable pin disables all internal circuits.

At the next turn-on, any voltage on the EN pin below the logic low voltage ensures a normal start-up waveform with start-up ramp rate control, provided there is enough time to discharge the output capacitance. If shutdown capability is not required, connect EN to IN. V_{EN} must not exceed V_{IN}.

7.3.6 Internal Foldback Current Limit

The internal foldback current-limit circuit is used to protect the LDO against high-load current faults or shorting events. The foldback mechanism lowers the current limit as the output voltage decreases, and limits power dissipation during short-circuit events while still allowing for the device to operate at its rated output current; see 图 29.

Feature Description (接下页)

A foldback example for this device is that when V_{OUT} is 90% of $V_{OUT(nom)}$ the current limit is I_{CL}(typical); however, if V_{OUT} is forced to 0 V the current limit is I_{SC} (typical).

In many LDOs the foldback current limit can prevent start-up into a constant-current load or a negatively-biased output. The foldback mechanism for this device goes into a brick-wall current limit when V_{OUT} > 500 mV (typ), thus limiting current to I_{CL}(typical) and, when V_{OUT} is approximately 0 V, current is limited to I_{SC} (typical) to ensure normal start-up into a variety of loads.

The foldback current limit is disengaged when I_{OUT} < 1 mA (typical) to reduce I_Q. As such, the current-limit loop takes longer to respond to a current-limit event when I_{OUT} < 1 mA (typ).

Thermal shutdown can activate during a current-limit event because of the high power dissipation typically found in these conditions. To ensure proper operation of the current limit, minimize the inductances to the input and load. Continuous operation in current limit is not recommended.

7.3.7 Thermal Shutdown

The device contains a thermal shutdown protection circuit to disable the device when thermal junction temperature (T_J) of the main pass-FET rises to $T_{sd(Shutdown)}$ (typical). Thermal shutdown hysteresis assures that the LDO resets again (turns on) when the temperature falls to $T_{sd(Reset)}$ (typical).

The thermal time-constant of the semiconductor die is fairly short, and thus the device may cycle on and off when thermal shutdown is reached until power dissipation is reduced.

For reliable operation, limit the junction temperature to a maximum of 125°C. Operation above 125°C causes the device to exceed its operational specifications. Although the internal protection circuitry of the device is designed to protect against thermal overload conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above a junction temperature of 125°C reduces long-term reliability.

A fast start-up when T_J > $T_{sd(Reset)}$ (typical, outside of the specified operating range) causes the device thermal shutdown to assert at $T_{sd(Reset)}$ and prevents the device from turning on until the junction temperature is reduced below $T_{sd(Shutdown)}$.

版权 © 2018–2019, Texas Instruments Incorporated

7.4 Device Functional Modes

The device has several modes of operation,:

- Normal operation: The device regulates to the nominal output voltage
- Dropout operation: The pass element operates as a resistor and the output voltage is set as $V_{IN} – V_{DO}$
- Shutdown: The output of the device is disabled and the discharge circuit is activated

表 1 shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

表 1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER			
	V_{IN}	V_{EN}	I_{OUT}	T_J
Normal mode	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	$V_{EN} > V_{EN(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{sd(Shutdown)}$
Dropout mode	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	$V_{EN} > V_{EN(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{sd(Shutdown)}$
Disabled mode (any true condition disables the device)	$V_{IN} < V_{UVLO}$	$V_{EN} < V_{EN(LO)}$	—	$T_J > T_{sd(Shutdown)}$

7.4.1 Normal Mode

The device regulates the output to the nominal output voltage when all normal mode conditions in 表 1 are met.

7.4.2 Dropout Mode

The device is not in regulation, and the output voltage tracks the input voltage minus the voltage drop across the pass transistor of the device. In this mode, the PSRR, noise, and transient performance of the device are significantly degraded.

7.4.3 Disable Mode

In this mode, the pass element is turned off, the internal circuits are shut down, and the output voltage is actively discharged to ground by an internal resistor.

8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Recommended Capacitor Types

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and COG-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. As a rule of thumb, assume effective capacitance to decrease by as much as 50%. The input and output capacitors recommended in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

8.1.2 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. An input capacitor is recommended if the source impedance is more than 0.5 Ω. A higher value capacitor may be necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved with the use of an output capacitor. Use an output capacitor within the range specified in the *Recommended Operating Conditions* table for stability.

8.1.3 Special Considerations When Ramping Down V_{IN} and Enable

Care must be taken when ramping down voltage on the IN and EN pins to power-down the device when the operating free-air temperature is less than 15°C. The minimum ramp-down time for the IN pin is 10 ms. The minimum ramp-down time for the EN pin is 100 µs. Ramping at faster rates can cause the regulator to exhibit undesired startup behavior on the next power-on.

If V_{IN} is ramped down faster than 10 ms, the next startup may exhibit a partial startup, shutoff, followed by a normal soft-start startup. 图 48 shows this response.

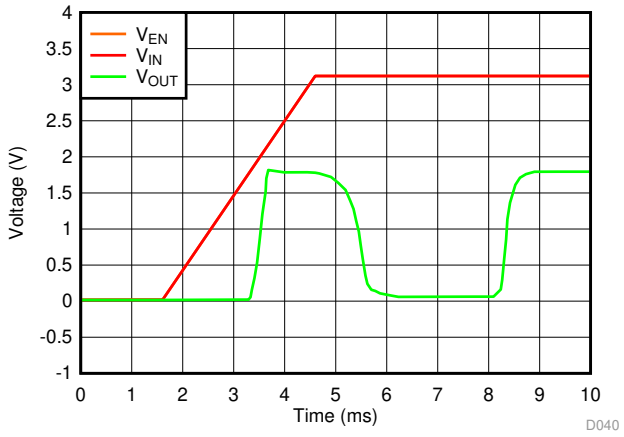


图 48. Partial Startup, Shutdown, Normal Startup With V_{EN} = V_{IN}

版权 © 2018–2019, Texas Instruments Incorporated

Application Information (接下页)

If the EN pin is ramped down faster than 100 µs, the next startup may exhibit a delay time of up to 130 ms before the output ramps up with a normal soft-start startup. 图 49 shows this delay.

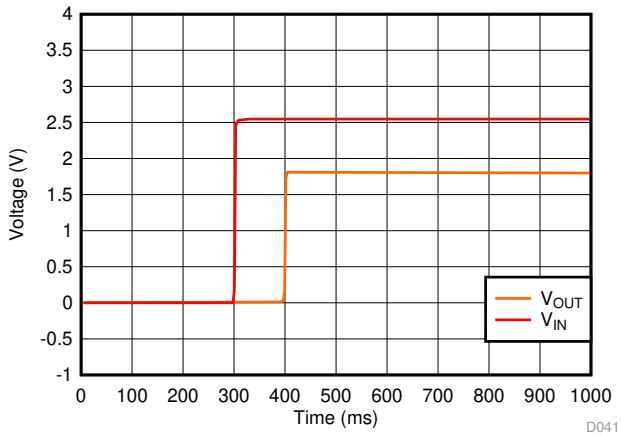


图 49. Long Delay to Startup With $V_{EN} = V_{IN}$

Fast ramp downs of V_{IN} and the EN pin charge internal high-impedance nodes in the device, which take extended time to discharge below 15°C. To avoid these startup behaviors, follow the recommended minimum ramp down times for V_{IN} and the EN pin.

8.1.4 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained. See 图 6 for typical load transient response. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load. The regions in 图 50 are broken down as described in this section. Regions A, E, and H are where the output voltage is in steady-state.

During transitions from a light load to a heavy load, the:

- Initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor (region B)
- Recovery from the dip results from the LDO increasing its sourcing current, and leads to output voltage regulation (region C)

During transitions from a heavy load to a light load, the:

- Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase (region F)
- Recovery from the rise results from the LDO decreasing its sourcing current in combination with the load discharging the output capacitor (region G)

A larger output capacitance reduces the peaks during a load transient but slows down the response time of the device. A larger dc load also reduces the peaks because the amplitude of the transition is lowered and a higher current discharge path is provided for the output capacitor.

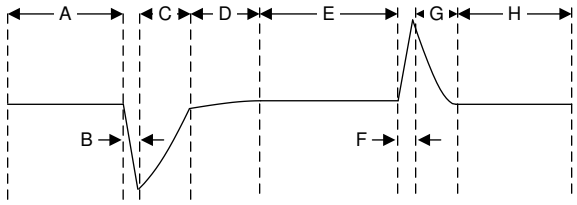


图 50. Load Transient Waveform

Application Information (接下页)

8.1.5 Dropout Voltage

The device uses a PMOS pass transistor to achieve low dropout. When (V_{IN} – V_{OUT}) is less than the dropout voltage (V_{DO}), the PMOS pass transistor is in the linear region of operation, and the input-to-output resistance of the device is the drain-to-source resistance of the PMOS pass transistor. V_{DO} scales with the output current and changes with temperature because the PMOS pass transistor functions like a resistor in dropout mode. For a graph of dropout voltage, see 图 22. As with any linear regulator, PSRR and the transient response degrade as (V_{IN} – V_{OUT}) approaches dropout operation. See 图 23 for dropout performance.

8.1.5.1 Behavior When Transitioning From Dropout Into Regulation

Some applications may have transients that place the device into dropout, especially as this device can be powered from a battery with high ESR. A typical application with these conditions is using a stack of two 1.55-V coin-cell batteries with an ESR of 30 Ω to create a 2.5-V rail and experiencing a load transient from 1 µA to 25 mA. This load transient causes the input supply to drop 750 mV, placing the device into dropout.

The load transient saturates the output stage of the error amplifier when the pass element is driven fully on, making the pass element function like a resistor from V_{IN} to V_{OUT}. The error amplifier response time to this load transient is limited because the error amplifier must first recover from saturation and then place the pass element back into active mode. During this time V_{OUT} overshoots because the pass element is functioning as a resistor from V_{IN} to V_{OUT}. This device uses a loop pulldown circuit to help mitigate the overshoot.

If operating under these conditions, applying a higher dc load or increasing the output capacitance reduces the overshoot because these solutions provide a path to dissipate the excess charge.

8.1.5.2 Behavior of Output Resulting From Line Transient When in Dropout

The output deviation resulting from a line transient can be significantly higher when the device is operating in dropout. As explained in the *Dropout Voltage* section, the response time of the error amplifier is limited when in dropout, so the output deviation is larger and can exceed twice the regulated output voltage. Care must be taken in applications where line transients are expected when the device is operating in dropout.

8.1.6 Undervoltage Lockout (UVLO) Operation

The UVLO circuit ensures that the device stays disabled before its input supply reaches the minimum operational voltage range, and ensures that the device shuts down when the input supply collapses. See 图 46 for rising and falling thresholds. 图 51 depicts the UVLO circuit response to various input voltage events. The diagram can be separated into the following parts:

- Region A: The device does not start until the input reaches the UVLO rising threshold
- Region B: Normal operation, regulating device
- Region C: Brownout event above the UVLO falling threshold (UVLO rising threshold – UVLO hystersis). The output may fall out of regulation but the device is still enabled.
- Region D: Normal operation, regulating device
- Region E: Brownout event below the UVLO falling threshold. The device is disabled in most cases and the output falls as a result of the load and active discharge circuit. The device is re-enabled when the UVLO rising threshold is reached by the input voltage and a normal start-up follows.
- Region F: Normal operation followed by the input falling to the UVLO falling threshold
- Region G: The device is disabled as the input voltage falls below the UVLO falling threshold to 0 V. The output falls as a result of the load and active discharge circuit.

版权 © 2018–2019, Texas Instruments Incorporated

Application Information (接下页)

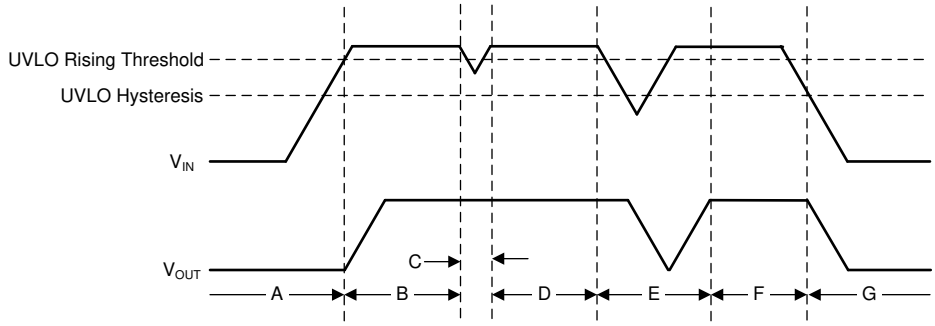


图 51. Typical UVLO Operation

8.1.7 Power Dissipation (P_D)

Circuit reliability demands that proper consideration be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

公式 2 calculates the maximum allowable power dissipation for the device in a given package:

$$P_{D\text{-}MAX} = ((T_J – T_A) / R_{\theta JA}) \quad (2)$$

公式 3 represents the actual power being dissipated in the device:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (3)$$

An important note is that power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A05 allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device depends on the ambient temperature and the thermal resistance across the various interfaces between the die junction and ambient air.

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. According to 公式 4, maximum power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A). The equation is rearranged in 公式 5 for output current.

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (4)$$

$$I_{OUT} = (T_J – T_A) / [R_{\theta JA} \times (V_{IN} – V_{OUT})] \quad (5)$$

Unfortunately, this thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in the *Thermal Information* table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. For a well-designed thermal layout, $R_{\theta JA}$ is actually the sum of the DQN package junction-to-case (bottom) thermal resistance ($R_{\theta JC(bot)}$) plus the thermal resistance contribution by the PCB copper.

Application Information (接下页)

8.1.7.1 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics (Ψ_{JT} and Ψ_{JB}) are used in accordance with 公式 6 and are given in the *Thermal Information* table.

$$\Psi_{JT} : T_J = T_T + \Psi_{JT} \times P_D \text{ and } \Psi_{JB} : T_J = T_B + \Psi_{JB} \times P_D$$

where:

- P_D is the power dissipated as explained in 公式 3
- T_T is the temperature at the center-top of the device package, and
- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge (6)

8.1.7.2 Recommended Area for Continuous Operation

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator is shown in 图 52 and can be separated into the following regions:

- Dropout voltage limits the minimum differential voltage between the input and the output ($V_{IN} – V_{OUT}$) at a given output current level; see the *Dropout Voltage* section for more details.
- The rated output currents limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- The rated junction temperature limits the maximum junction temperature of the device. Exceeding this rating causes the device to fall out of specification and reduces long-term reliability.
  - 公式 5 provides the shape of the slope. The slope is nonlinear because the maximum rated junction temperature of the LDO is controlled by the power dissipation across the LDO, thus when $V_{IN} – V_{OUT}$ increases the output current must decrease.
- The rated input voltage range governs both the minimum and maximum of $V_{IN} – V_{OUT}$.

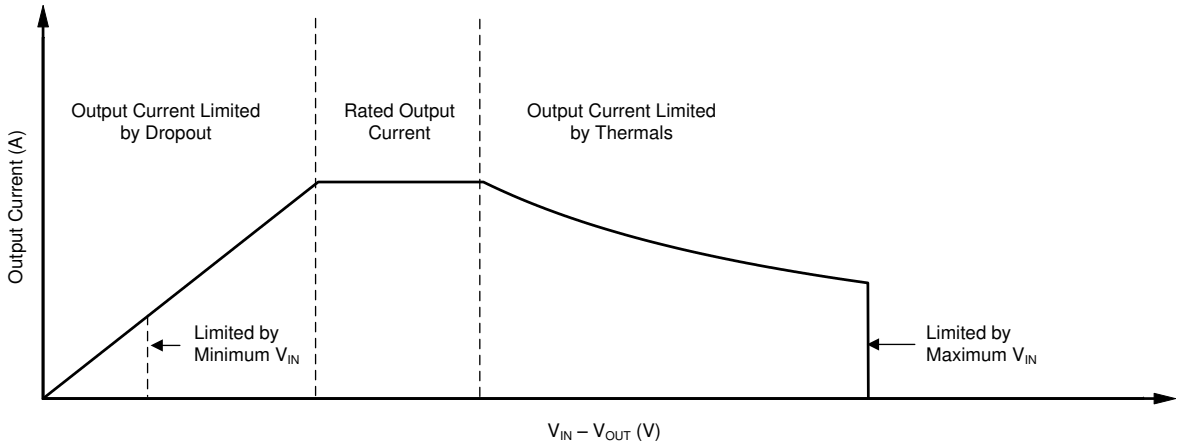


图 52. Region Description for Continuous Operation

版权 © 2018–2019, Texas Instruments Incorporated

8.2 Typical Application

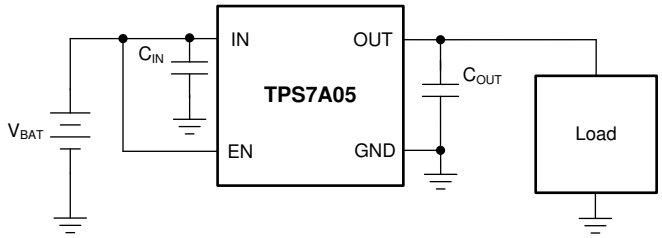


图 53. Operation From the Battery Input Supply

8.2.1 Design Requirements

表 2 summarizes the design requirements for 图 53.

表 2. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	3.0 V to 2.0 V (CR2032 battery)
Output voltage	1.0 V, ±2% (T_J from –40 to +85ºC)
Output load	10 mA

8.2.2 Design Considerations

For this design example, the 1.0-V, fixed-version TPS7A0510 device is selected. A single CR2032 coin-cell battery was used, thus a 1.0-µF input capacitor is recommended to minimize transient currents drawn from the battery. A 1.0-µF output capacitor is also recommended for excellent load transient response. The dropout voltage (V_{DO}) is kept within the TPS7A05 dropout voltage specification for the 1.0-V output voltage option to keep the device in regulation under all load and temperature conditions for this design. The very small ground current consumed by the regulator shown in 图 54 allows for long battery life.

8.2.3 Application Curve

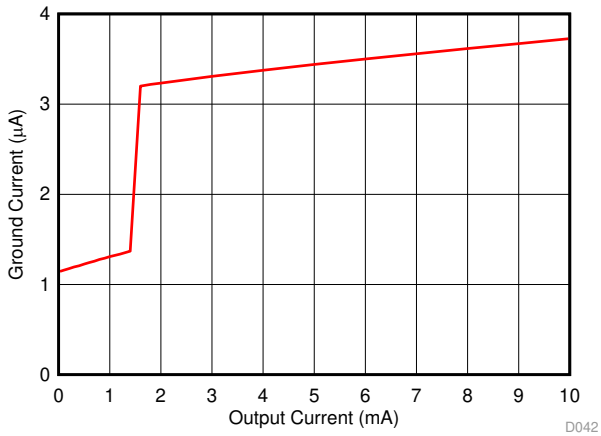


图 54. I_{GND} vs I_{OUT} at 25°C

9 Power Supply Recommendations

This device is designed to operate from an input supply voltage range of 1.4 V to 5.5 V. The input supply must be well regulated and free of spurious noise. To ensure that the output voltage is well regulated and dynamic performance is optimum, the input supply must be at least $V_{OUT(nom)}$ + 0.5 V. A 1 µF or greater input capacitor is recommended to be used to reduce the impedance of the input supply, especially during transients.

10 Layout

10.1 Layout Guidelines

- Place input and output capacitors as close to the device as possible
- Use copper planes for device connections to optimize thermal performance
- Place thermal vias around the device to distribute heat
- Do not place a thermal via directly beneath the thermal pad of the DQN package. A via can wick solder or solder paste away from the thermal pad joint during the soldering process, leading to a compromised solder joint on the thermal pad.

10.2 Layout Example

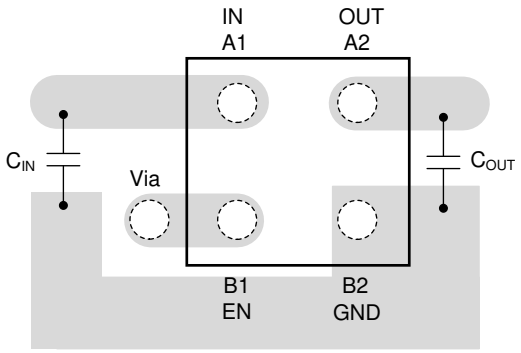


图 55. Layout Example for the YKA Package

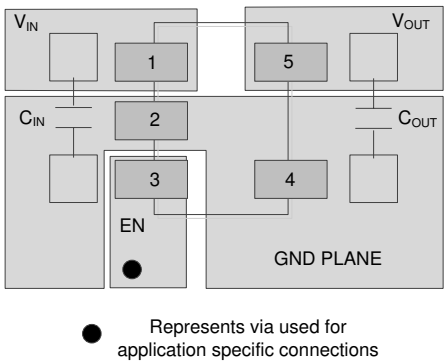


图 56. Layout Example for the DBV Package

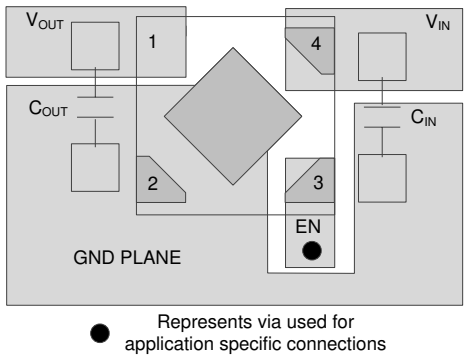


图 57. Layout Example for the DQN Package

版权 © 2018–2019, Texas Instruments Incorporated

11 器件和文档支持

11.1 器件支持

11.1.1 Spice 模型

您可以从产品文件夹中的*工具与软件*下获取 TPS7A05 的 SPICE 模型。

11.1.2 器件命名规则

表 **3.** 器件命名规则 (1) (2)

产品	V_{OUT}
TPS7A05**xx(x)Pyyyz**	**xx(x)** 为标称输出电压。对于分辨率为 100mV 的输出电压，订货编号中使用两位数字；否则，使用三位数字（例如，28 = 2.8V；125 = 1.25V）。 **P** 是可选的；P 表示有源输出放电功能。 **yyy** 为封装标识符。 **z** 为封装数量。R 表示卷（3000 片），T 表示带（250 片）。

(1) 要获得最新的封装和订货信息，请参阅本文档末尾的封装选项附录，或者访问器件产品文件夹（www.ti.com.cn）。
(2) 可提供 1.0V 至 3.3V 范围内的输出电压（以 50mV 为单位增量）。更多详细信息及可用性，请联系制造商。

11.2 文档支持

11.2.1 相关文档

请参阅如下相关文档：

《通用低压降 (LDO) 线性稳压器 MultiPkgLDOEVM-823 评估模块》

11.3 接收文档更新通知

要接收文档更新通知，请导航至 TI.com.cn 上的器件产品文件夹。单击右上角的*通知我* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

11.4 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 商标

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.6 静电放电警告

ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。 精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

11.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

版权 © 2018–2019, Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A0508PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1C6F
TPS7A0508PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1C6F
TPS7A0508PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1C6F
TPS7A0508PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1C6F
TPS7A0508PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QMW
TPS7A0508PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QMW
TPS7A0508PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QMW
TPS7A0508PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QMW
TPS7A0508PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	6G
TPS7A0508PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	6G
TPS7A0508PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	6G
TPS7A0508PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	6G
TPS7A0508PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	3
TPS7A0508PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	3
TPS7A0510PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IKF
TPS7A0510PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IKF
TPS7A0510PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IKF
TPS7A0510PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IKF
TPS7A0510PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7
TPS7A0510PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7
TPS7A0510PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7
TPS7A0510PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7
TPS7A0510PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	L
TPS7A0510PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	L
TPS7A0511PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HK
TPS7A0511PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HK
TPS7A0512PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	1ILF
TPS7A0512PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1ILF
TPS7A0512PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1ILF

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A0512PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1ILF
TPS7A0512PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QOW
TPS7A0512PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QOW
TPS7A0512PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QOW
TPS7A0512PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QOW
TPS7A0512PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C8
TPS7A0512PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C8
TPS7A0512PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C8
TPS7A0512PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C8
TPS7A0512PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	M
TPS7A0512PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	M
TPS7A0515PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	1IMF
TPS7A0515PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IMF
TPS7A0515PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IMF
TPS7A0515PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IMF
TPS7A0515PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C9
TPS7A0515PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C9
TPS7A0515PDQNR1	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C9
TPS7A0515PDQNR1.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C9
TPS7A0515PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C9
TPS7A0515PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C9
TPS7A0515PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	N
TPS7A0515PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	N
TPS7A051825PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	P
TPS7A051825PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	P
TPS7A0518PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	1INF
TPS7A0518PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1INF
TPS7A0518PDBVRG4	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1INF
TPS7A0518PDBVRG4.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1INF
TPS7A0518PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1INF
TPS7A0518PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1INF

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A0518PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QQW
TPS7A0518PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QQW
TPS7A0518PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QQW
TPS7A0518PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QQW
TPS7A0518PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA
TPS7A0518PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA
TPS7A0518PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA
TPS7A0518PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA
TPS7A0518PDQNTG4	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA
TPS7A0518PDQNTG4.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA
TPS7A0518PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	P
TPS7A0518PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	P
TPS7A0518YKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	N
TPS7A0518YKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	N
TPS7A0520PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U8W
TPS7A0520PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U8W
TPS7A0520PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U8W
TPS7A0520PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U8W
TPS7A0520PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	G1
TPS7A0520PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	G1
TPS7A0522PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P3F
TPS7A0522PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P3F
TPS7A0522PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P3F
TPS7A0522PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P3F
TPS7A0522PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U9W
TPS7A0522PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U9W
TPS7A0522PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U9W
TPS7A0522PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1U9W
TPS7A0525PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IOF
TPS7A0525PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IOF
TPS7A0525PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IOF

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A0525PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IOF
TPS7A0525PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB
TPS7A0525PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB
TPS7A0525PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB
TPS7A0525PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB
TPS7A0525PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Q
TPS7A0525PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Q
TPS7A0527PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1UAW
TPS7A0527PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1UAW
TPS7A0527PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1UAW
TPS7A0527PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1UAW
TPS7A05285PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IRF
TPS7A05285PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IRF
TPS7A05285PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IRF
TPS7A05285PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IRF
TPS7A05285PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC
TPS7A05285PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC
TPS7A05285PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC
TPS7A05285PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC
TPS7A05285PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	R
TPS7A05285PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	R
TPS7A0528PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QSW
TPS7A0528PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QSW
TPS7A0528PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QSW
TPS7A0528PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QSW
TPS7A0528PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DH
TPS7A0528PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DH
TPS7A0528PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DH
TPS7A0528PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DH
TPS7A0530PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QWF
TPS7A0530PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QWF

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A0530PDBVRG4	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QWF
TPS7A0530PDBVRG4.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QWF
TPS7A0530PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QWF
TPS7A0530PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QWF
TPS7A0530PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QUW
TPS7A0530PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QUW
TPS7A0530PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QUW
TPS7A0530PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QUW
TPS7A0530PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DG
TPS7A0530PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DG
TPS7A0530PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DG
TPS7A0530PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DG
TPS7A0530PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	W
TPS7A0530PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	W
TPS7A0531PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P4F
TPS7A0531PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P4F
TPS7A0531PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P4F
TPS7A0531PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1P4F
TPS7A0531PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	I6
TPS7A0531PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	I6
TPS7A0533PDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	1IPF
TPS7A0533PDBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IPF
TPS7A0533PDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IPF
TPS7A0533PDBVT.A	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1IPF
TPS7A0533PDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QVW
TPS7A0533PDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QVW
TPS7A0533PDBZT	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QVW
TPS7A0533PDBZT.A	Active	Production	SOT-23 (DBZ) | 3	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1QVW
TPS7A0533PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD
TPS7A0533PDQNR.A	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD
TPS7A0533PDQNT	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A0533PDQNT.A	Active	Production	X2SON (DQN) | 4	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD
TPS7A0533PYKAR	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	S
TPS7A0533PYKAR.A	Active	Production	DSBGA (YKA) | 4	12000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	S

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

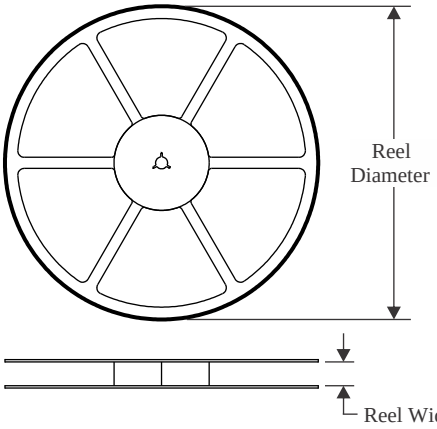
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

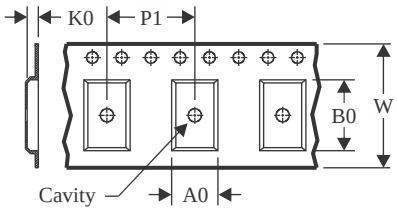
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

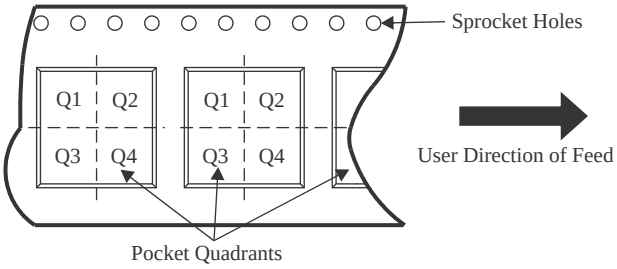


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



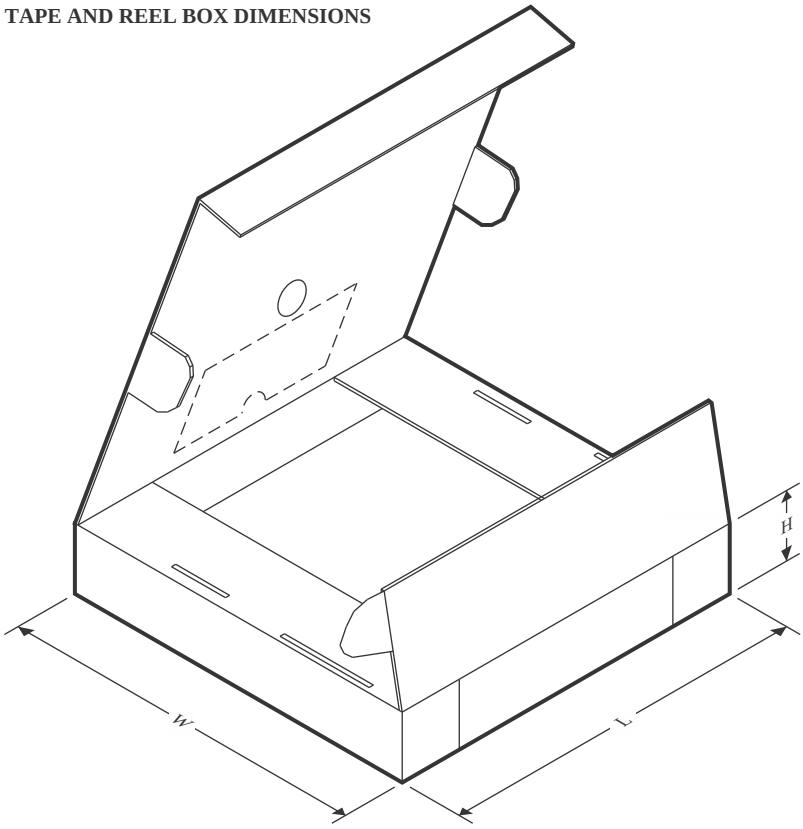
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A0508PDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0508PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0508PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0508PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0508PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0508PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0508PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0510PDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0510PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0510PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0510PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0510PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0511PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0512PDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0512PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0512PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A0512PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0512PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0512PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0512PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0515PDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0515PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0515PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0515PDQNR1	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q1
TPS7A0515PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0515PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A051825PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0518PDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0518PDBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0518PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0518PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0518PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0518PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0518PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0518PDQNTG4	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0518PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0518YKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0520PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0520PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0520PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0522PDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0522PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0522PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0522PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0525PDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0525PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0525PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0525PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0525PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0527PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0527PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A05285PDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A05285PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A05285PDQNR	X2SON	DQN	4	3000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A05285PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A05285PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A05285PDQNT	X2SON	DQN	4	250	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A05285PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0528PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0528PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0528PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0528PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0530PDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0530PDBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0530PDBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0530PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0530PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0530PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0530PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0530PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0530PDQNR	X2SON	DQN	4	3000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0530PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0530PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1
TPS7A0531PDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0531PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0531PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0533PDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0533PDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7A0533PDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0533PDBZT	SOT-23	DBZ	3	250	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
TPS7A0533PDQNR	X2SON	DQN	4	3000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0533PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0533PDQNT	X2SON	DQN	4	250	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A0533PYKAR	DSBGA	YKA	4	12000	180.0	8.4	0.76	0.76	0.46	2.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A0508PDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0508PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0508PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0508PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0508PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0508PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0508PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0510PDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0510PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0510PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0510PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0510PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0511PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0512PDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TPS7A0512PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0512PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0512PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0512PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A0512PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0512PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0515PDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TPS7A0515PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0515PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0515PDQNR1	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0515PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0515PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A051825PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0518PDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TPS7A0518PDBVRG4	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0518PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0518PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0518PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0518PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0518PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0518PDQNTG4	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0518PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0518YKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0520PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0520PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0520PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0522PDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0522PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0522PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0522PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0525PDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0525PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0525PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0525PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0525PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0527PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0527PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A05285PDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A05285PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A05285PDQNR	X2SON	DQN	4	3000	184.0	184.0	19.0
TPS7A05285PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A05285PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A05285PDQNT	X2SON	DQN	4	250	184.0	184.0	19.0
TPS7A05285PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0528PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0528PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0528PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A0528PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0530PDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TPS7A0530PDBVRG4	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0530PDBVRG4	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0530PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0530PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0530PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0530PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0530PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0530PDQNR	X2SON	DQN	4	3000	184.0	184.0	19.0
TPS7A0530PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0530PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0
TPS7A0531PDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7A0531PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0531PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0533PDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TPS7A0533PDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS7A0533PDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
TPS7A0533PDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
TPS7A0533PDQNR	X2SON	DQN	4	3000	184.0	184.0	19.0
TPS7A0533PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A0533PDQNT	X2SON	DQN	4	250	210.0	185.0	35.0
TPS7A0533PYKAR	DSBGA	YKA	4	12000	182.0	182.0	20.0

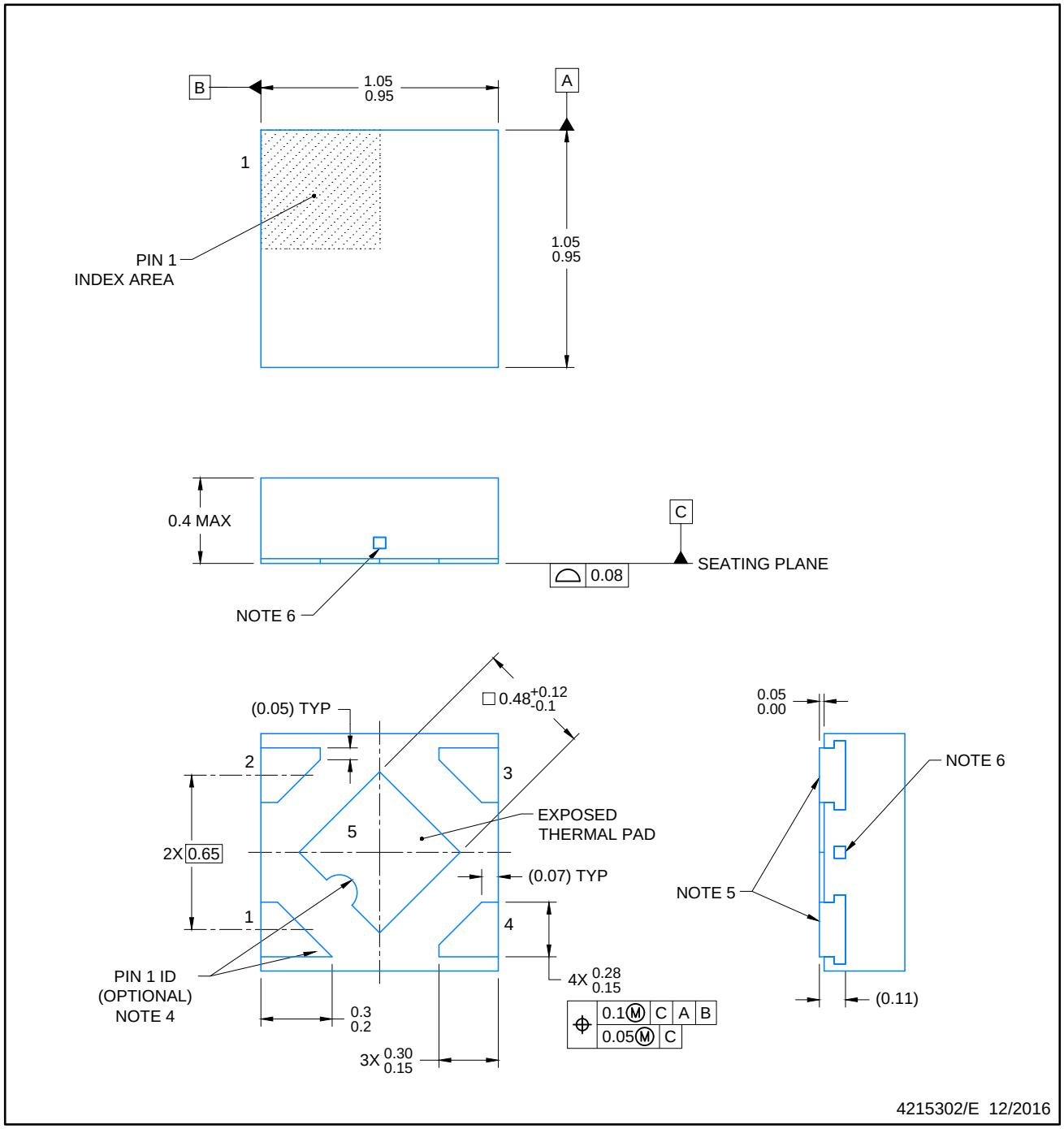
DQN 4

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

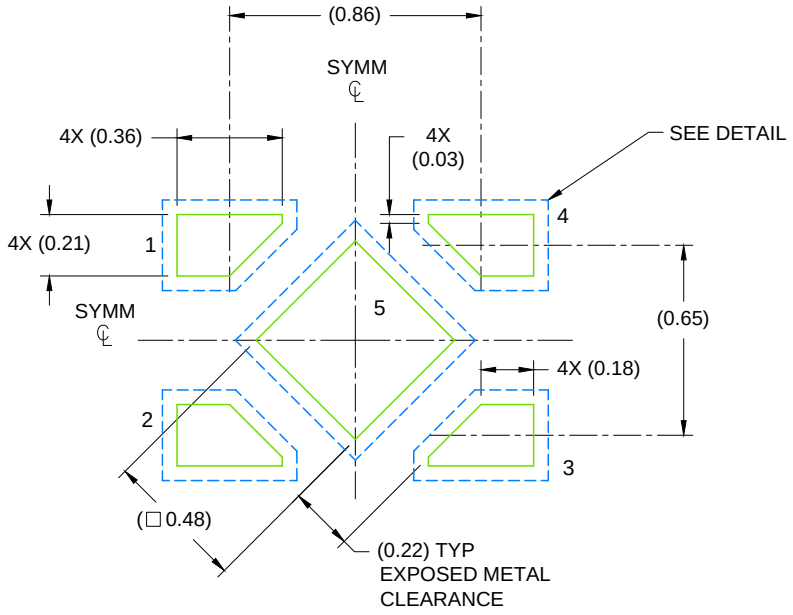
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

TEXAS INSTRUMENTS

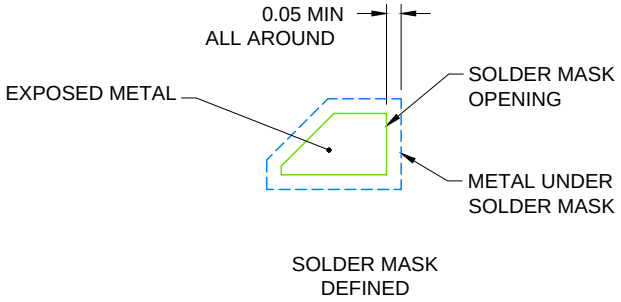


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.
4. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.
5. Shape of exposed side leads may differ.
6. Number and location of exposed tie bars may vary.



LAND PATTERN EXAMPLE
SCALE: 40X

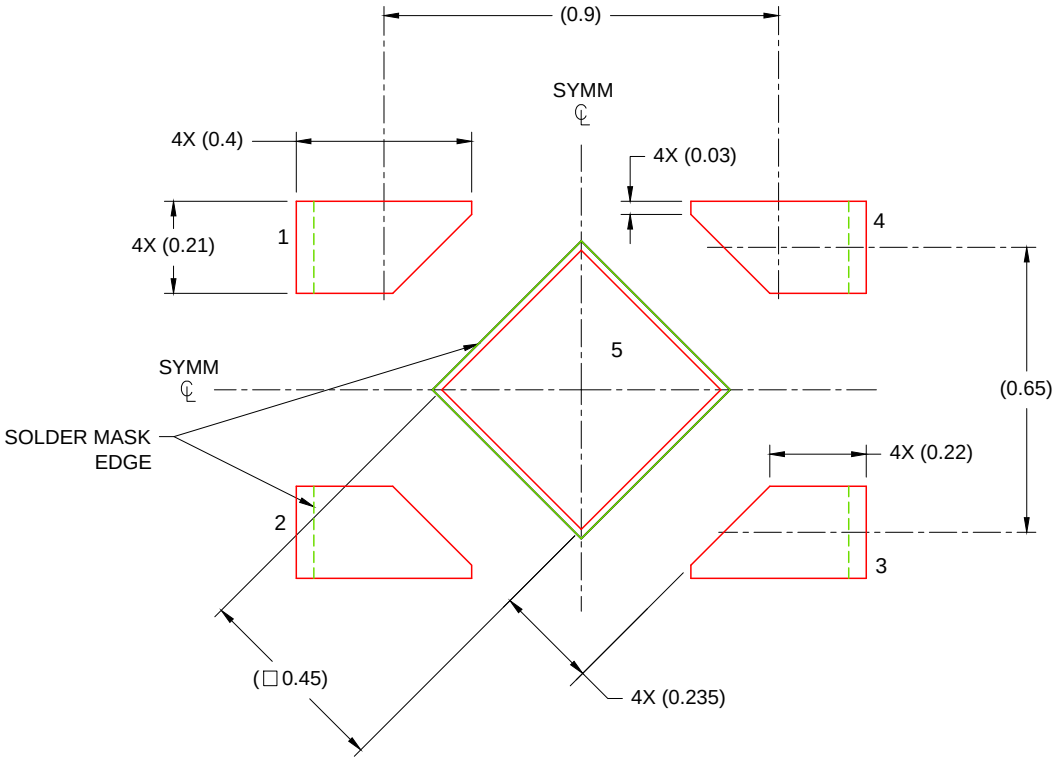


SOLDER MASK DETAIL

4215302/E 12/2016

NOTES: (continued)

7. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
8. If any vias are implemented, it is recommended that vias under paste be filled, plugged or tented.



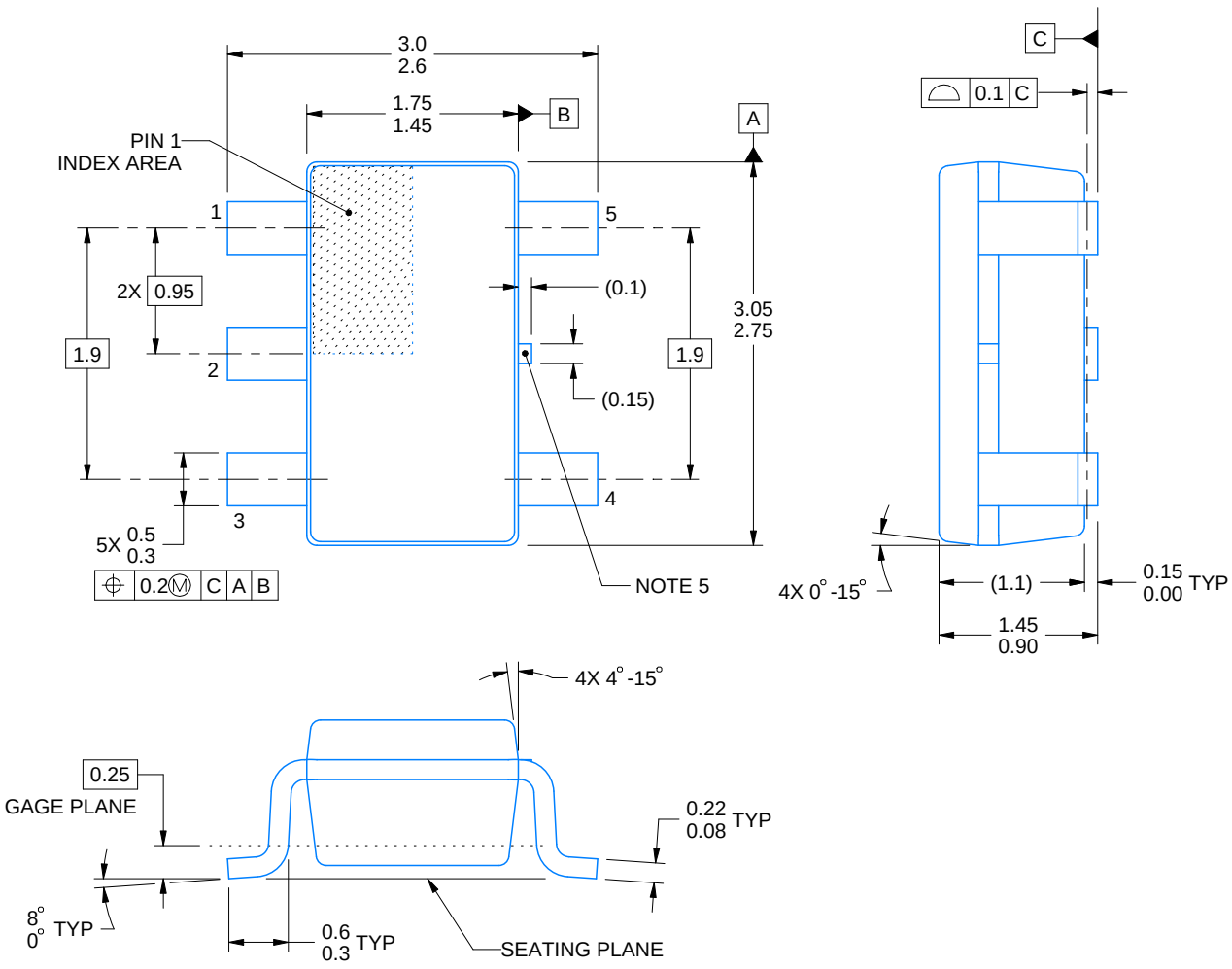
SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1mm THICK STENCIL

EXPOSED PAD
88% PRINTED SOLDER COVERAGE BY AREA
SCALE: 60X

4215302/E 12/2016

NOTES: (continued)

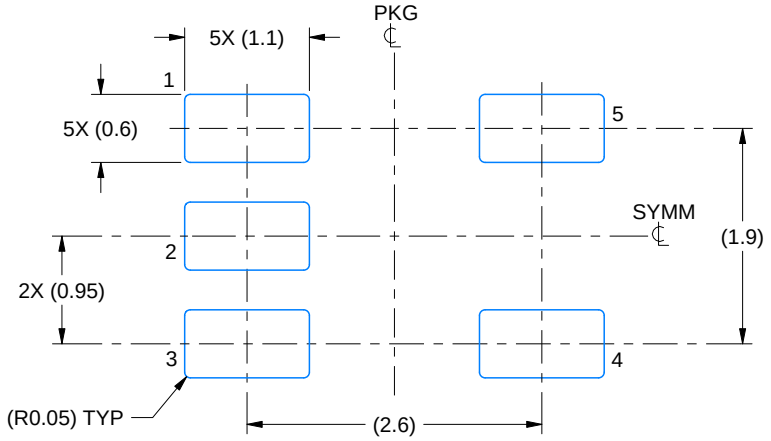
9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



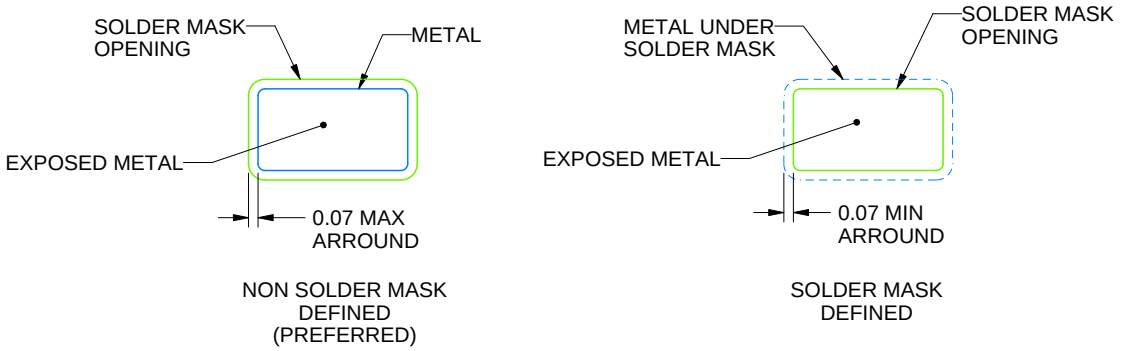
4214839/K 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

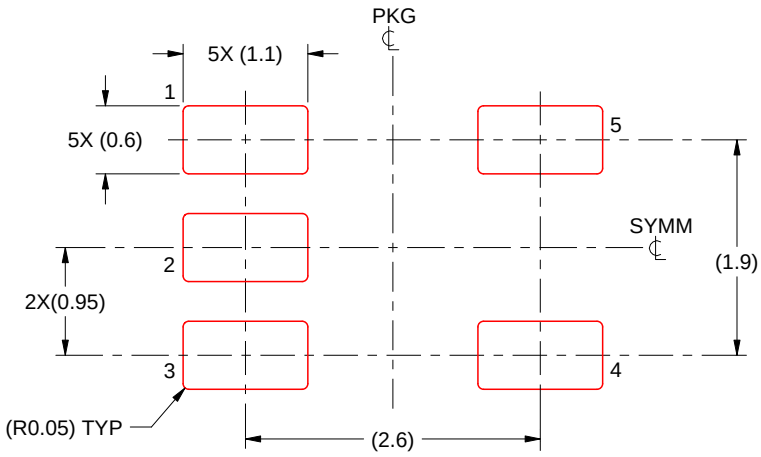


SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

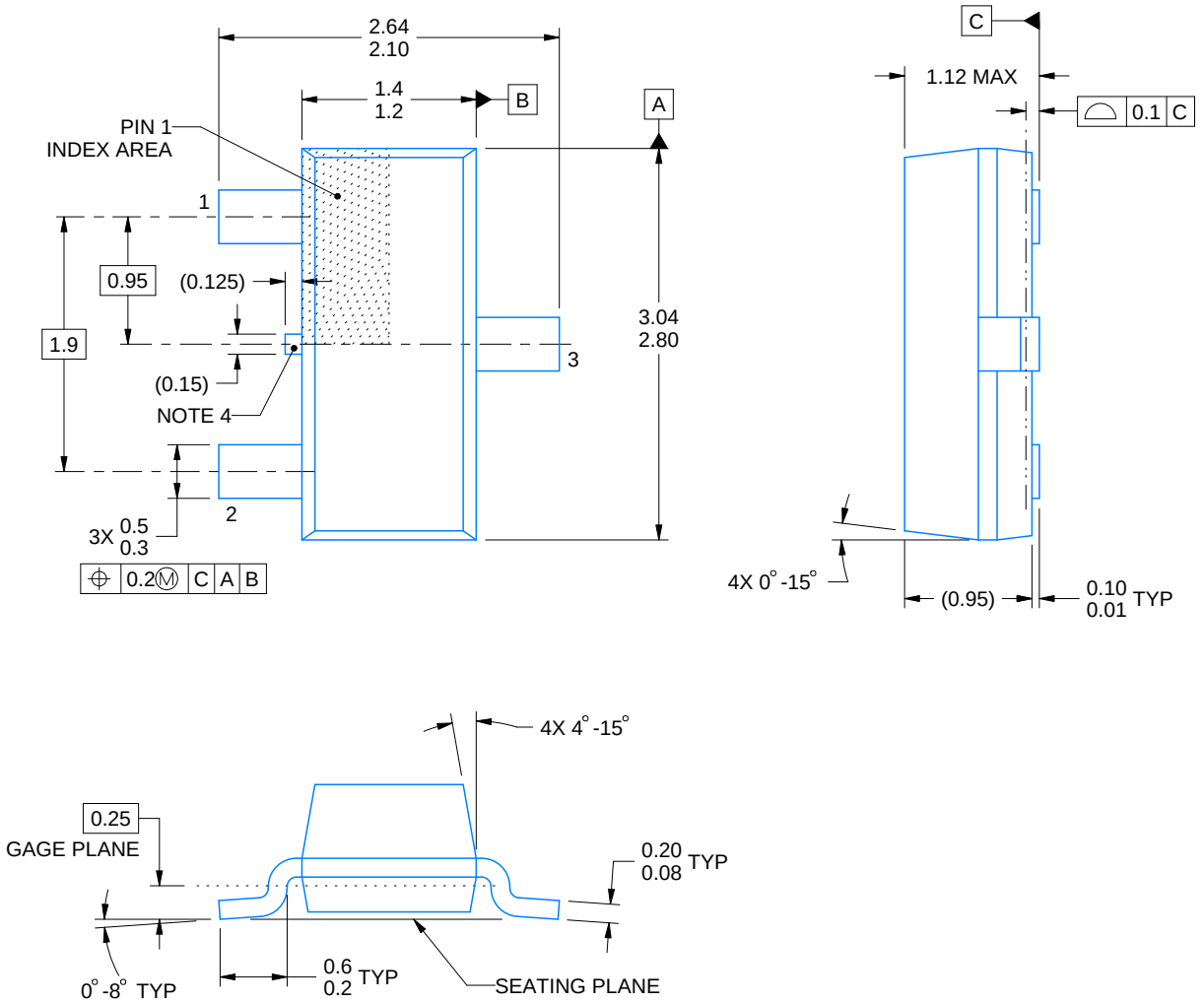


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

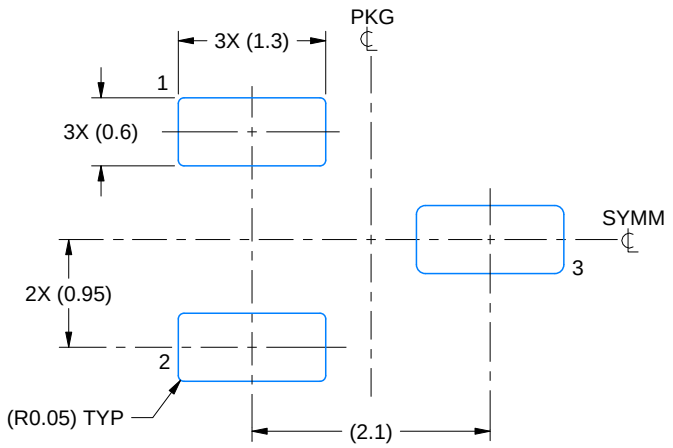
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



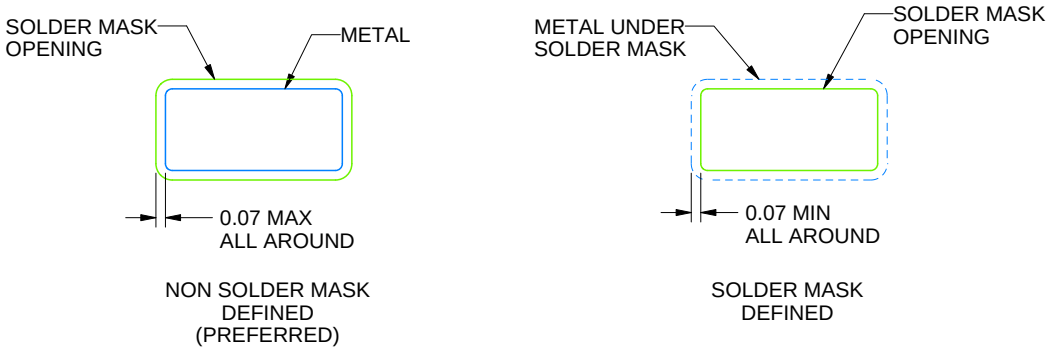
4214838/F 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



LAND PATTERN EXAMPLE
SCALE:15X

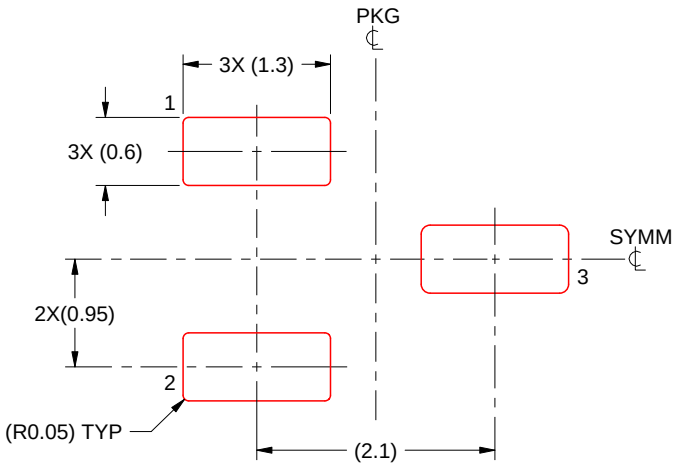


SOLDER MASK DETAILS

4214838/F 08/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

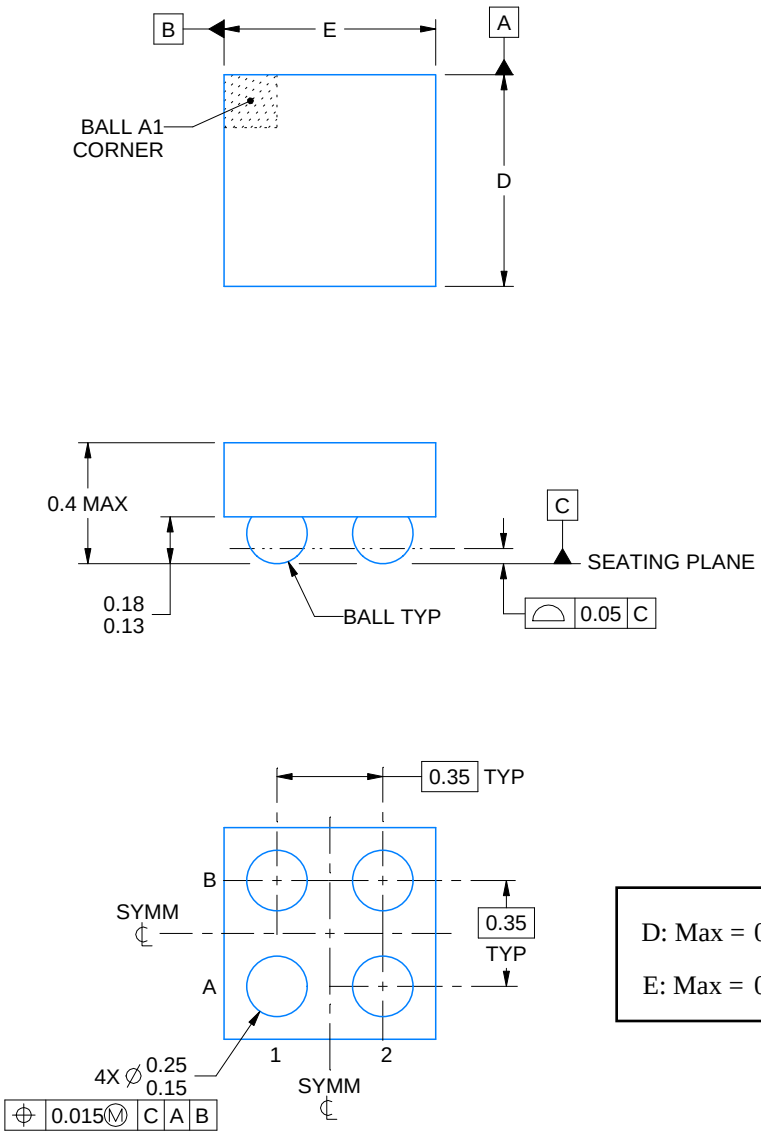


SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/F 08/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



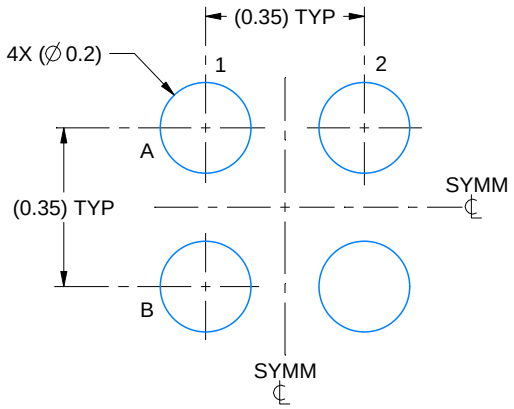
D: Max = 0.694 mm, Min =0.634 mm

E: Max = 0.694 mm, Min =0.634 mm

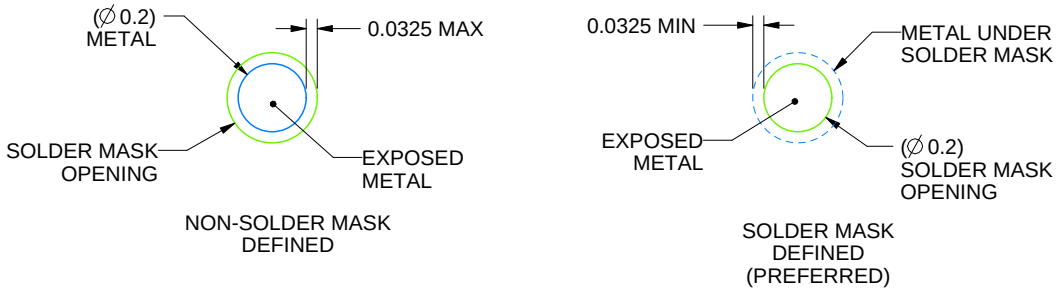
4221909/B 08/2018

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:60X

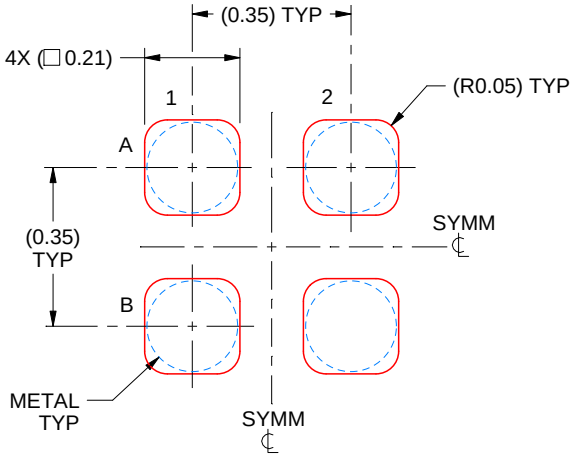


SOLDER MASK DETAILS
NOT TO SCALE

4221909/B 08/2018

NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



SOLDER PASTE EXAMPLE
BASED ON 0.075 mm - 0.1 mm THICK STENCIL
SCALE:60X

4221909/B 08/2018

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

重要通知和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做出任何明示或暗示的担保，包括但不限于对适销性、与某特定用途的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他安全、安保法规或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。对于因您对这些资源的使用而对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，您将全额赔偿，TI 对此概不负责。

TI 提供的产品受 TI 销售条款)、TI 通用质量指南 或 ti.com 上其他适用条款或 TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。 除非德州仪器 (TI) 明确将某产品指定为定制产品或客户特定产品，否则其产品均为按确定价格收入目录的标准通用器件。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

版权所有 © 2026，德州仪器 (TI) 公司

最后更新日期：2025 年 10 月